NTM88Hxx5S

Tire pressure monitor sensor

Rev. 1.1 — 23 June 2023 Objective data sheet



1 General description

The NTM88 family consists of small (4 mm x 4 mm x 1.98 mm), fully integrated tire pressure monitoring sensors (TPMS). The devices described in this data sheet, NTM88Hxx5S, provide low transmitting power consumption, large customer memory size, and single- or dual-axis accelerometer architecture. The NTM88Hxx5S TPMS solution integrates an 8-bit microcontroller (MCU), pressure sensor, accelerometers in five ranges, programmable RF transmitter and flexible LF receiver. The sensor supports seven GPIOs, client SPI, and a 2-channel timer / pulse-width module.

2 Features and benefits

- Optional pressure ranges[1]
- Optional accelerometer ranges: See Section 3.
- Transducer measurement interfaces with low-power AFE:
  - 10-bit compensated pressure sense element
  - 10-bit compensated accelerometers
  - 8-bit compensated internal device temperature measurement
  - 8-bit compensated internal device voltage measurement
  - Two I/O pins can be used for external signals
- 8-bit S08 compact instruction set controller:
  - 64 bytes low-power “always on“ NVM parameter registers
  - 512 bytes SRAM
  - 16 kB flash memory (512 bytes reserved for NXP coefficients)
  - Family of NXP firmware libraries available via royalty-free license
- Programmable RF transmitter
  - Characterized for RF carrier typical of 315 MHz or 434 MHz
  - Characterized for FSK in ~3 kHz increments or OOK modulation
  - Characterized for baud rate examples of 9.6 kbp/s, 19.2 kbp/s, and 38.4 kbp/s
- Flexible 125 kHz LF receiver:
  - Capability for ASK or OOK demodulation
  - Automated Manchester decoding
- Two channel timer / pulse-width module
- Client SPI to support host access to internal peripherals, registers, and memory
- Seven GPIOs with programmable multiplexing to support software development, external analog voltage input, timer, SPI, and wake-up
- Qualified in compliance with AEC-Q100, Rev. H

1 Consult NXP sales for details or specific requests.

- Long battery service life
- Internal temperature sensor
- Internal voltage sensor
- Six-channel, 8-, 10-, or 12-bit analog-to-digital converter (ADC10) with two external I/O inputs
- Internal 315-/434-M Hz RF transmitter
  - External crystal oscillator
  - PLL-based output with fractional-n divider
  - OOK and FSK modulation capability
  - Programmable data rate generator
  - Manchester, Bi-Phase, or NRZ data encoding
  - 256-bit RF data buffer variable length interrupt
  - Direct access to RF transmitter from MCU for unique formats
  - Low-power consumption
- Differential input LF detector/decoder on independent signal pins
- Real-time Interrupt driven by LFO with intervals of 2, 4, 8, 16, 32, 64, or 128 ms
- Free-running counter, low-power, wake up timer and periodic reset driven by LFO
- Watchdog timeout with selectable times and clock sources
- Two-channel general-purpose timer/PWM module (TPM1)
- Internal oscillators
  - MCU bus clock of 0.5, 1, 2, and 4 MHz (1, 2, 4, and 8 MHz HFO)
  - Low frequency, low-power time clock (LFO) with 1 ms period
  - Medium frequency, controller clock (MFO) of 8 µs period
- Low-voltage detection

3 Ordering information

Table 1. Ordering information

Type number	Package		
	Name	Description	Version
NTM88Hxx5S	HQFN24	Plastic thermal enhanced quad flat package; no leads, 0.1 dimple wettable flank; 24 terminals; 0.5 mm pitch, 4 mm x 4 mm x 1.98 mm body	SOT1931-1(D)

Table 2. Ordering options

Part Number 'N8'	Pressure Range 'p'	Accelerometer 'aa'		X-axis Range	Z-axis Range	CodeH Hardware (First Rev)[1]
NTM88H025ST1[2]	90 kPa to 930 kPa 'H'	Z	'02'	N/A	–360 g to +400 g	$92
NTM88H055ST1[2]		X	'05'	–80 g to +90 g	NA	$95
NTM88H065ST1[2]			'06'	–360 g to +400 g		$96
NTM88H075ST1[2]			'07'	–120 g to +520 g		$97
NTM88H125ST1[2]		XZ	'12'	–400 g to +400 g	–175 g to +550 g	$9C
NTM88H135ST1[2]			'13'	–80 g to +90 g	–360 g to +400 g	$9D
NTM88H145ST1[2]			'14'	–360 g to +400 g	–80 g to +90 g	$9E
NTM88H155ST1[2]			'15'	-360 g to +400 g	-360 g to +400 g	$9F

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[1] The value CodeF mentioned in the User Manual UM11227[1] depicts the version of firmware used by NXP during device tests, and will become $FF as the device is shipped. The value of CodeF will be replaced again by the version number of the firmware library used by the customer at the time of device final application programming.

[2] Product under development, consult your NXP sales representatives for samples.

3.1 Hardware version numbers

The hardware version numbers are located in two bytes, both hexadecimal values indicating the version number of the bill-of-materials used to construct the sensor. Both are programmed in the NTM88 device.

The hardware version numbers are programmed by NXP in the NTM88 flash at production and can be read by the host MCU via SPI at addresses $1542 and $1543 under certain conditions.

Below tables detail the content of the data bytes stored at SPI addresses $1542 and $1543.

Table 3. Content of the hardware version byte at SPI address $1542

BIT7	BIT6	BIT5	BIT4	BIT3	BIT2	BIT1	BIT0
MCU revision				**Package revision**			
0b1111 = 1st version 0b1110 = 1st revision 0b1101 = 2nd revision etc…				0b1111 = 1st version 0b1110 = 1st revision 0b1101 = 2nd revision etc…			

Table 4. Content of the hardware version byte at SPI address $1543

BIT7	BIT6	BIT5	BIT4	BIT3	BIT2	BIT1	BIT0
Reserved				**Pressure transducer**			
Note: *Reserved bits may not all have the same value. Some bits may read as 1 and others as 0, and as such should be ignored until further notice.*				Pressure transducer 0b0000 = not present 0b1111 = 1st version 0b1110 = 1st revision 0b1101 = 2nd revision			

The hardware version numbers can be read by the host MCU only when BIT0, BIT1 and BIT2 of SPIOPS register are all equal to 1. In other words, when SPIOPS register is equal to value 0x07. Any attempt to read the hardware version numbers while SPIOPS register is not equal to 0x07 will result in an incorrect reading of the version numbers.

The sequence to implement on the host MCU side to read the hardware version numbers is the following:

1. Send a READ BYTE command to SPIOPS address $0038. The resulting 16-bit SPI command is equal to 0x00E1.
2. In the SPI response to the READ BYTE command, check the value of SPIOPS register:
   - If BIT2 of SPIOPS register is clear, this indicates that communication with the NTM88 has not been successfully established.
   - If BIT2 of SPIOPS is set, but BIT1 and/or BIT0 is clear, the host MCU should send a WRITE BYTE command to SPIOPS address $0038 to write value 0x07. The resulting 16-bit SPI commands are equal to 0x80E3 followed by 0x801F.
   - If SPIOPS register is equal to 0x07, no further action on SPIOPS register is needed.
3. Send a READ BYTE command to SPI addresses $1542 and/or $1543. The resulting 16-bit SPI command is equal to 0x550A for address $1542 and 0x550F for address $1543. Table 5 through Table 8 detail the format of the commands and responses.

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Table 5. 16-bit SPI command to read the NTM88 hardware version at SPI address $1542

16-bit command = 0x550A															
READ	Address = 0x1542													Parity	
0	a12	a11	a10	a9	a8	a7	a6	a5	a4	a3	a2	a1	a0	p1	p0
0	1	0	1	0	1	0	1	0	0	0	0	1	0	1	0

Table 6. 16-bit SPI command to read the NTM88 hardware version at SPI address $1543

16-bit command = 0x550F															
READ	Address = 0x1543													Parity	
0	a12	a11	a10	a9	a8	a7	a6	a5	a4	a3	a2	a1	a0	p1	p0
0	1	0	1	0	1	0	1	0	0	0	0	1	1	1	1

When the 16-bit SPI command 0x550A is sent to the NTM88, a possible 16-bit response is 0x03FF, indicating that the package and MCU revisions are both first version.

Table 7. Example of SPI response from the NTM88 to the command 0x550A

16-bit response = 0x03FF															
READ	Status = 0					Data = 0xFF								Parity	
0	s4	s3	s2	s1	s0	d7	d6	d5	d4	d3	d2	d1	d0	p1	p0
						MCU revision				Package revision					
0	0	0	0	0	0	1	1	1	1	1	1	1	1	1	1

When the 16-bit SPI command 0x550F is sent to the NTM88, a possible 16-bit response is 0x03FF, indicating that the pressure transducer revision is first version.

Table 8. Example of SPI response from the NTM88 to the command 0x550F

16-bit response = 0x03FF															
READ	Status = 0					Data = 0xFF								Parity	
0	s4	s3	s2	s1	s0	d7	d6	d5	d4	d3	d2	d1	d0	p1	p0
						Reserved				Pressure transducer					
0	0	0	0	0	0	1	1	1	1	1	1	1	1	1	1

In the examples of SPI response given above, the SPI status bits are equal to 0. In case the SPI response includes status bits different from 0, see UM11227[1] to decode the status.

The host reading an SPI response equal to 0x0000 may indicate that communication has not been successfully established with the NTM88 device.

4 Block diagram

Figure 1 presents the device's main blocks and their signal interactions. Power management controls and bus control signals are not shown in this block diagram for clarity.

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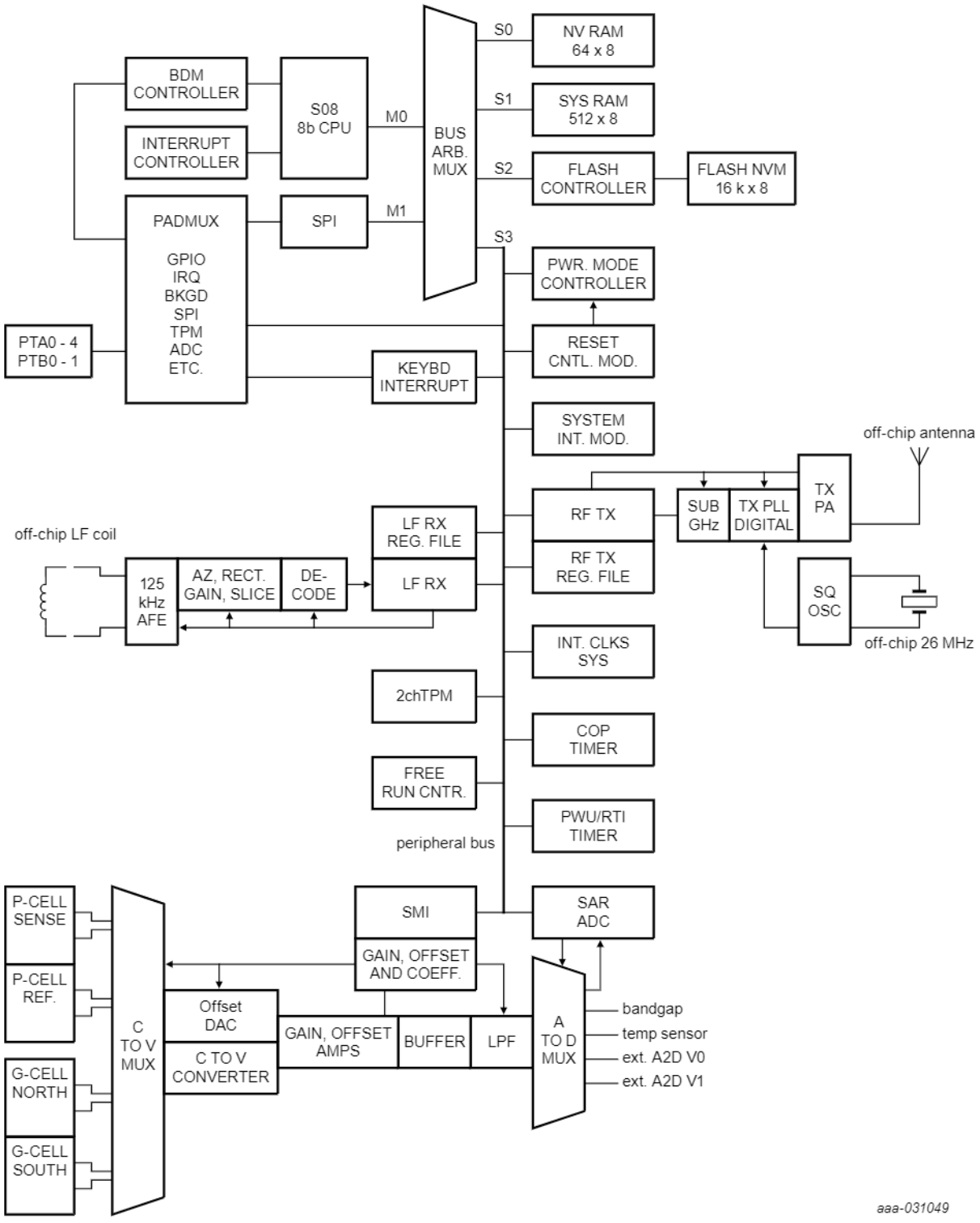


Figure 1. Block diagram

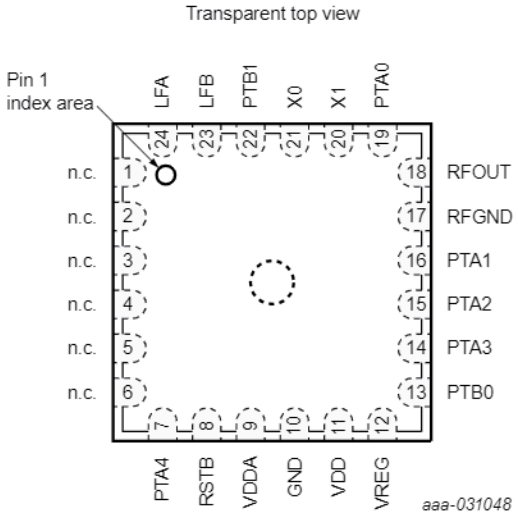
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5 Pinning information

5.1 Pinning

A top view of the device pint with the pressure port on top is show in Figure 2. The orientation of the internal Z-axis accelerometer is shown in Figure 3.



Note: *Pins 1-6 are mechanically and electrically connected to the central flag; See Section 9.*

Figure 2. Pin configuration

5.2 Pin description

Table 9. Pin description

Symbol	Pin	Function	Description
n.c.	1	—	Do not connect electrical signals to this pin; solder joint only.
n.c.	2	—	Do not connect electrical signals to this pin; solder joint only.
n.c.	3	—	Do not connect electrical signals to this pin; solder joint only.
n.c.	4	—	Do not connect electrical signals to this pin; solder joint only.
n.c.	5	—	Do not connect electrical signals to this pin; solder joint only.
n.c.	6	—	Do not connect electrical signals to this pin; solder joint only.
PTA4	7	PTA4 / BKGD	PTA4 Pin - The PTA4 pin places the device in the BACKGROUND DEBUG mode (BDM) to evaluate MCU code and transfer data to/from the internal memory. If the BKGD/PTA4 pin is held low when the device comes out of a power-on-reset (POR), the device switches into the ACTIVE BACKGROUND DEBUG mode (BDM). The BKGD/PTA4 pin has an internal pullup device or can be connected to VDD in the application, unless there is a need to enter BDM operation after the device as been soldered into the PWB. If in-circuit BDM is desired, the BKGD/PTA4 pin should be connected to VDD through a resistor (~10 kΩ or greater) which can be over-driven by an external signal. This resistor reduces the possibility of inadvertently activating the debug mode in the application due to an EMC event. When the application programs port A to GPIOs, PTA4 becomes output-only.

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Table 9. Pin description...*continued*

Symbol	Pin	Function	Description
RST_B	8	Reset / V_{PP} programming voltage	The RST_B pin is used for test and establishing the BDM condition and providing the programming voltage source to the internal FLASH memory. This pin can also be used to direct to the MCU to the reset vector. The RST_B pin has an internal pullup device and can be connected to VDD in the application unless there is a need to enter BDM operation after the device as been soldered to the PWB. If in-circuit BDM is desired, the RST_B pin can be left unconnected; but should be connected to VDD through a low impedance resistor (<10 kΩ) which can be over-driven by an external signal. This low impedance resistor reduces the possibility of getting into the debug mode in the application due to an EMC event. Activation of the external reset function occurs when the voltage on the RST_B pin goes below 0.3 × V_{DD} for at least 100 ns before rising above 0.7 × V_{DD}.
VDDA	9	Analog supply	The analog circuits operate from a single power supply connected to the unit through the VDDA pin. VDDA is the positive supply and GND is the ground. The conductors to the power supply should be connected to the VDDA and GND pins and locally decoupled. Care should be taken to reduce measurement signal noise by separating the VDD, GND, VDDA, and RFGND pins using a “star” connection such that each metal trace does not share any load currents with other external devices.
GND	10	Digital and analog ground	The digital circuits operate from a single power supply connected to the unit through the VDD and GND pins. GND is the ground. Care should be taken to reduce measurement signal noise by separating the GND and RFGND pins using a “star” connection such that each metal trace does not share any load currents with other external devices.
VDD	11	Digital supply	The digital circuits operate from a single power supply connected to the unit through the VDD and GND pins. VDD is the positive supply. The conductors to the power supply should be connected to the VDD and GND pins and locally decoupled.
VREG	12	1.8 V regulation	The internal regulator for the RF analog circuits requires an external stabilization capacitor to GND.
PTB0	13	PTB0 / TPMCH0 / AD3	The PTB[0] pin is a general-purpose I/O pin. This pin can be configured as a nominal bidirectional I/O pin with programmable pullup devices. User software must configure the general-purpose I/O pin (PTB[1:0]) so that they do not result in “floating” inputs. PTB0 can be mapped to TPM channel 0, or to ADC channel 3.
PTA3	14	PTA3 / KBI3 / MOSI	The PTA[3] pin is a general-purpose I/O pin. The pulldown devices can only be activated if the wake-up interrupt capability is enabled. User software must configure the general-purpose I/O pins so that they do not result in “floating” inputs. PTA[3] maps to keyboard interrupt function bit [3]. When SPI is enabled, PTA[3] serves as MOSI.
PTA2	15	PTA2 / KBI2 / MISO	The PTA[2] pin is a general-purpose I/O pin. The pulldown devices can only be activated if the wake-up interrupt capability is enabled. User software must configure the general-purpose I/O pins so that they do not result in “floating” inputs. PTA[2] maps to keyboard interrupt function bit [2]. When SPI is enabled, PTA[2] serves as MISO.
PTA1	16	PTA1 / KBI1 / SCLK	The PTA[1] pin is a general-purpose I/O pin. The pulldown devices can only be activated if the wake-up interrupt capability is enabled. User software must configure the general-purpose I/O pins so that they do not result in

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Table 9. Pin description*...continued*

Symbol	Pin	Function	Description
			"floating" inputs. PTA[1] maps to keyboard interrupt function bit [1]. When SPI is enabled, PTA[1] serves as SCLK
RFGND	17	RF ground	Power in the RF output amplifier is returned to the supply through the RFGND pin. This conductor should be connected to the power supply using a "star" connection such that each metal trace does not share any load currents with other supply pins.
RFOUT	18	RF output	The RFOUT pin is the RF energy data supplied by the unit to an external antenna.
PTA0	19	PTA0 / KBI0 / SS_B / IRQ	The PTA[0] pin is a general-purpose I/O pin. PTA[0] can be configured as a normal bidirectional I/O pin with programmable pullup or pulldown devices and/or wake-up interrupt capability. PTA[0] can be configured for external interrupt (IRQ). The pulldown devices can only be activated if the wake-up interrupt capability is enabled. User software must configure the general-purpose I/O pins so that they do not result in "floating" inputs. PTA[0] maps to keyboard interrupt function bit [0]. When SPI is enabled, PTA0 serves as SS_B.
X1	20	RF crystal input	The X1 pin is for an external 26 MHz crystal to be used by the internal PLL for creating the carrier frequencies and data rates for the RF pin.
X0	21	RF crystal output	The X0 pin is for an external 26 MHz crystal to be used by the internal PLL for creating the carrier frequencies and data rates for the RF pin.
PTB1	22	PTB1 / TPMCH1 / AD4	The PTB[1] pin is a general-purpose I/O pin. This pin can be configured as a nominal bidirectional I/O pin with programmable pullup devices. User software must configure the general-purpose I/O pins (PTB[1:0]) so that they do not result in "floating" inputs. PTB1 can be mapped to TPM channel 1, or to ADC channel 4.
LFB	23	LF input '-'	The LF[A:B] pins can be used by the LF receiver (LFR) as one differential input channel for sensing low-level signals from an external low frequency (LF) coil. The external LF coil should be connected between the LF[A] and the LF[B] pins. Signaling into the LFR pins can place the unit into various diagnostic or operational modes. The LFR is comprised of the detector and the decoder. Each LF[A:B] pin always has an impedance of approximately 500 kΩ to GND due to the LFR input circuitry. The LFA/LFB pins are used by the LFR when the LFEN control bit is set and are not functional when the LFEN control bit is clear.
LFA	24	LF input '+'	The LF[A:B] pins can be used by the LF receiver (LFR) as one differential input channel for sensing low-level signals from an external low frequency (LF) coil. The external LF coil should be connected between the LF[A] and the LF[B] pins. Signaling into the LFR pins can place the unit into various diagnostic or operational modes. The LFR is comprised of the detector and the decoder. Each LF[A:B] pin always has an impedance of approximately 500 kΩ to GND due to the LFR input circuitry. The LFA/LFB pins are used by the LFR when the LFEN control bit is set and are not functional when the LFEN control bit is clear.

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5.3 Orientation

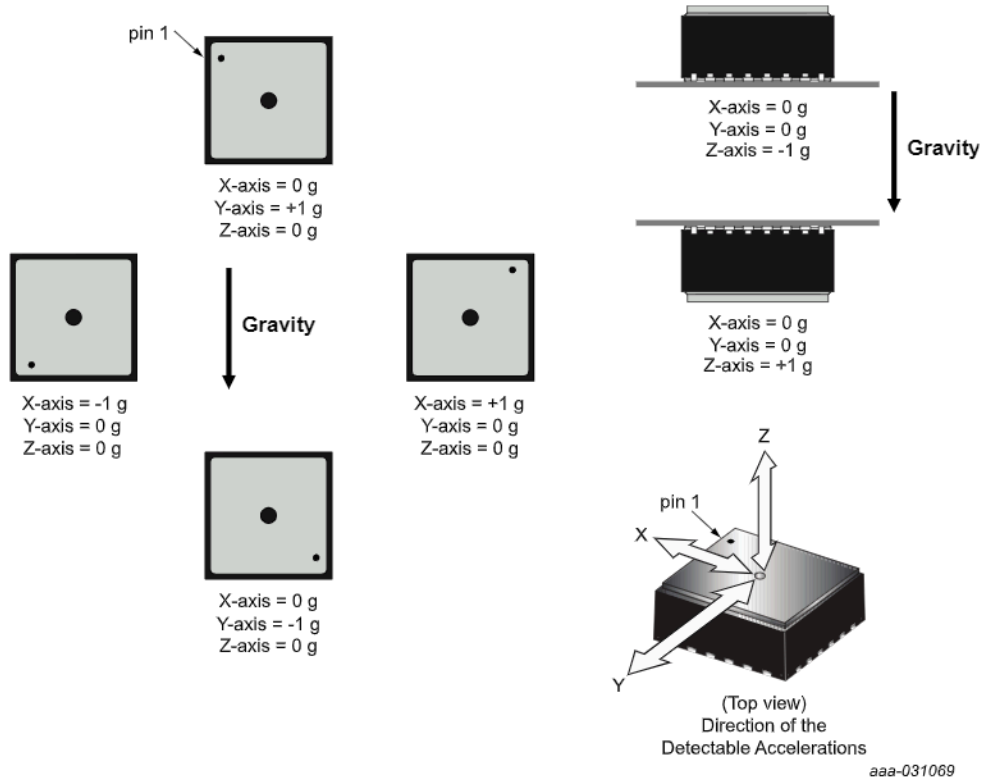


Figure 3. NTM88Hxx5S orientation at rest.

6 Electrical specifications

Tables in the electrical and mechanical specification sections of this data sheet may contain hyperlinked note references in the last cell of the row. The hyperlinks are linked to and defined in Table 10.

Table 10. Electrical and mechanical specification note definition table

Note identifier	Description
A	Parameters tested 100 % at final test.
B	Parameters tested 100 % at unit probe.
C	Verified by characterization, not tested in production.
D	For information only, may be determined by simulation.

6.1 Maximum ratings (electrical)

Maximum ratings are the extreme limits the device can be exposed to without permanently damaging it. The device contains circuitry to protect the inputs against damage from high static voltages; however, do not apply voltages higher than the values shown in Table 11. Keep V_{IN} and V_{OUT} within the range $V_{SS} \leq (V_{IN}$ or $V_{OUT}) \leq V_{DD}$.

In all cases of transient environment, the sensor functional behaviors, parametric behaviors, and dimensions may deviate from the listed steady-state environment tolerances as compared to external reference(s). τ is the characteristic thermal time constant, from device case ambient to the on-die temperature transducer. Transient

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environment means less than 2.3 × τ seconds since the last step-function transient of a condition; pressure, motion, temperature, supply voltage, electro-magnetic, humidity, vapor, media. Steady-state environment means 2.3 × τ or more seconds of stable conditions; pressure, motion, temperature, supply voltage, electro-magnetic, humidity, vapor, media. Examples of step-function transient condition might be tire blow-out, drop impact, ice-bath submersion, battery connection 'bounce', nearby radio transmitter, and so forth.

Table 11. Maximum ratings

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
V_{DD}	V_{DD} or V_{DDA} to V_{SS}	$T_L \le T_A \le T_h$	–0.3	—	3.6	V	C
V_{IO}	IO pin current, each pin vs V_{DD} / V_{DDA} or V_{SS}	T_{AS} Min ≤ T_A ≤ T_A Max	V_{SS} – 0.3	—	V_{dd} + 0.3	V	C
I_{IO}	IO pin current, pin vs V_{DD} / V_{DDA} or V_{SS}	$T_L \le T_A \le T_H$, V_{DDR} Min ≤ V_{DD} ≤ V_{DDR} Max	–10	—	10	mA	C
I_{SUBIO}	Substrate current injection, all IO pins except LFA LFB current from pin to V_{SS} – 0.3 V	$T_L \le T_A \le T_H$, V_{DDR} Min ≤ V_{DD} ≤ V_{DDR} Max	—	600	—	µA	C
I_{SUBLF}	Substrate current injection, LFA LFB current from pin to V_{SS} – 0.3 V	$T_L \le T_A \le T_H$, V_{DDF} Min ≤ V_{DD} ≤ V_{DDF} Max	—	2	—	mA	C
I_{LATCH}	Latch-up current, current to/from pin to V_{DD} / V_{DDA} + 0.3 V	$T_L \le T_A \le T_H$, V_{DDR} Min ≤ V_{DD} ≤ V_{DDR} Max	–100	—	100	mA	C
ESD_{HBM}	Electrostatic discharge, human body model (HBM), all pins except RF, and LF	T_A = 25 °C, V_{DD} = 3.0 V	–2000	—	2000	V	C
ESD_{HBM}	Electrostatic discharge, human body model (HBM), RF, and LF	T_A = 25 °C, V_{DD} = 3.0 V	–2000	—	2000	V	C
ESD_{CDM}	Electrostatic discharge, charged device model (CDM), all pins	T_A = 25 °C, V_{DD} = 3.0 V	–500	—	500	V	C
T_{STG}	Unpowered storage, temperature range	—	–50	—	150	°C	C

6.2 Operating conditions

The limits normally expected in the application that define the range of operation.

Table 12. Operating range

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
V_{DDR}	Operating voltage range, Parameter register retention where Min = V_L, Typ = 3.0 V, Max = V_H	T_{AS} Min ≤ T_A ≤ T_{AS} Max	1.2	3.0	3.6	V	C
V_{DDS}	Operating voltage range, MCU and SW, Flash Read, RF TX, Voltage Measurement where Min = V_L, Typ = 3.0 V, Max = V_H	T_{AS} Min ≤ T_A ≤ T_{AS} Max	V_{LVDRF}	3.0	3.6	V	C
V_{DDM}	Operating voltage range, Pressure, Temperature and Acceleration Measurements where Min = V_L, Typ = 3.0 V, Max = V_H	T_{AS} Min ≤ T_A ≤ T_{AS} Max	2.1	3.0	3.6	V	C
V_{DDF}	Operating voltage range, Flash Programming and LF RX, where Min = V_L, Typ = 3.0 V, Max = V_H	–20 °C ≤ T_A ≤ 85 °C	2.1	3.0	3.6	V	C
T_{AS}	Operating temperature range, Full functionality except LF RX, and Flash Programming where Min = T_L, Typ = 25 °C, Max = T_H	V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max	–40	25	125	°C	C

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Table 12. Operating range...*continued*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
T_{AF}	Operating temperature range, Operating voltage range, Full functionality, including LF RX, and Flash programming	V_{DDF} Min ≤ V_{DD} ≤ V_{DDF} Max	–20	25	85	°C	C
T_{A-EXC}	Operating temperature range excursion; 12 excursions of 15 minutes ea. (all Tolerances may be out of spec)	V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max	—	—	150	°C	C
I_{DD1}	Supply Current; Stop1 Mode (only LFO, PWU, and param. reg. On)	Typ = 25 °C, 3.0 V, Max = T_{AS} Min to Max & V_{DDR} Min to Max	—	0.18	18	µA	B
I_{DD4}	Supply Current; Stop4 Mode (only MCU, RF, and LF disabled)	Typ = 25 °C, 3.0 V, Max = T_{AS} Min to Max & V_{DDS} Min to Max	—	75	125	µA	B
I_{DDLFS}	Supply Current; Standby LF sniff (and Stop1 equivalent)	Typ = 25 °C, 3.0 V, Max = T_{AF} Min to Max & V_{DDF} Min to Max	—	4.8	8.1	µA	C
I_{DDLFD}	Supply Current; Standby LF Decoding (and Stop1 equivalent)	Typ = 25 °C, 3.0 V, Max = T_{AF} Min to Max & V_{DDF} Min to Max	—	11.3	14.3	µA	C
i_{DDR5K}	Supply Current; MCU Run 500 kHz (and RF and LF disabled)	Typ = 25 °C, 3.0 V, Max = T_{AS} Min to Max & V_{DDS} Min to Max	—	0.8	1.0	mA	C
I_{DDR1M}	Supply Current; MCU Run 1 MHz (and RF and LF disabled)	Typ = 25 °C, 3.0 V, Max = T_{AS} Min to Max & V_{DDS} Min to Max	—	1.0	1.2	mA	C
I_{DDR2M}	Supply Current; MCU Run 2 MHz (and RF and LF disabled)	Typ = 25 °C, 3.0 V, Max = T_{AS} Min to Max & V_{DDS} Min to Max	—	1.42	1.6	mA	C
I_{DDR4M}	Supply Current; MCU Run 4 MHz (and RF and LF disabled)	Typ = 25 °C, 3.0 V, Max = T_{AS} Min to Max & V_{DDS} Min to Max	—	2.1	2.5	mA	B
I_{DDRFT3}	Supply Current; RF TX 5 dBm, 315 MHz (and Stop1 equivalent)	T_A = 25 °C, V_{DD} = 3.0 V	—	5.7	6.1	mA	B
I_{DDRFT4}	Supply Current; RF TX 5 dBm, 434 MHz (and Stop1 equivalent)	T_A = 25 °C, V_{DD} = 3.0 V	—	6.3	6.8	mA	B
$I_{DDRFTx1}$	Supply Current Increase w/ BOOST = 1 RF TX 5 dBm (and Stop1 equivalent)	T_A = 25 °C, V_{DD} = 3.0 V	—	—	0.6	mA	C
I_{DDIF0}	Supply Current, RF Interframe period, IFPD = 0	Typ = 25 °C, 3.0 V, Max = T_{AS} Min to Max & V_{DDS} Min to Max	—	610	870	µA	C
I_{DDIF1}	Supply Current, RF Interframe period, IFPD = 1	Typ = 25 °C, 3.0 V, Max = T_{AS} Min to Max & V_{DDS} Min to Max	—	19	36	µA	C
I_{DDA} or I_{DDP}	Supply Current Peak; Accel. or Pressure Measurements (and Stop4 equivalent)	Typ = 25 °C, 3.0 V, Max = T_{AS} Min to Max & V_{DDM} Min to Max	—	2.8	3.15	mA	C
I_{DDV} or I_{DDT}	Supply Current Peak; Voltage or Temp. Measurements (and Stop4 equivalent)	Typ = 25 °C, 3.0 V, Max = T_{AS} Min to Max & V_{DDM} Min to Max	—	2.8	3.8	mA	C

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6.3 Charge consumptions

Table 13. Charge consumptions

$T_L \le T_A \le T_H$, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
Q_{wake}	Stop1 to run charge consumption, F_{bus} set for 4 MHz	V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max	—	0.10	—	µA-sec	C
QPA_{r512}	Pressure or accelerometer charge consumption; Raw 512 µs settling per sample	V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max	—	0.95	—	µA-sec	C
QPA_{r2048}	Pressure or accelerometer charge consumption; Raw 2048 µs settling per sample	V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max	—	1.85	—	µA-sec	C
QP_{c3}	Pressure charge consumption; Compensation third order per sample	V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max	—	1.77	—	µA-sec	D
QA_{c2}	Accelerometer charge consumption; Compensation second order per sample	V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max	—	1.95	—	µA-sec	D
QVT_{r50}	Voltage or temperature charge consumption; Raw 50 µs conversion per sample	V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max	—	0.2	—	µA-sec	C
QVT_{c250}	Voltage or temperature charge consumption; Compensation ~0.25 ms per sample	V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max	—	0.50	—	µA-sec	D

6.4 Clocks and thresholds

Table 14. Clocks and thresholds

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
f_{BUS}	MCU bus frequency multiple of HFO	V_{DD} > V_{LVDRF}	—	0.5	—	x HFO	D
f_{HF0}	High frequency oscillator, multiple of MFO	V_{DD} > V_{LVDRF}	—	64	—	x MFO	D
t_{HFOST}	Stabilization time	—	—	300	1000	µs	D
f_{MFO}	Medium frequency oscillator	V_{DD} > V_{LVDRF}	107	125	135	kHz	A
f_{LFO}	Low frequency oscillator	—	504	—	1512	Hz	B
f_{LFRO}	LFR Clock (derived from LFRO)	—	120	129	139	kHz	B
t_{STOP1}	MCU wake-up time	From Stop1 to 1st instruction, 4 MHz	—	50	70	µs	C
t_{STOP4}	MCU wake-up time	From Stop4 to 1st instruction, 4 MHz	—	25	35	µs	C
t_{LV}	Low voltage times	V_{DD} < V_{LVx}	—	—	10	µs	D
V_{LVWLF}	Low voltage warning (LVW)	Lower threshold, V_{DD} falling	1.95	—	2.2	V	C
V_{LVWLR}	Low voltage warning (LVW)	Lower threshold, V_{DD} rising	2.02	—	2.1	V	C
V_{LVWHF}	Low voltage warning (LVW)	Higher threshold, V_{DD} falling	2.28	—	2.54	V	C
V_{LVWHR}	Low voltage warning (LVW)	Higher threshold, V_{DD} rising	2.34	—	2.61	V	C
V_{LVDLF}	Low voltage detection (LVD)	Lower threshold, V_{DD} falling	1.79	—	1.96	V	C
V_{LVDLR}	Low voltage detection (LVD)	Lower threshold, V_{DD} rising	1.87	—	2.03	V	C

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Table 14. Clocks and thresholds...*continued*

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
V_{LVDHF}	Low voltage detection (LVD)	Higher threshold, V_{DD} falling	1.95	—	2.2	V	C
V_{LVDHR}	Low voltage detection (LVD)	Higher threshold, V_{DD} rising	2.02	—	2.1	V	C
V_{LVDRF}	RF LVD	V_{DD} falling	1.6	—	2.1	V	C
T_{FDR}	Flash memory data retention	—	10	—	—	Yr	D

6.5 Power-on reset operation

When power is initially applied to the device, or when the supply voltage drops below the V_{POR} level, the POR circuit causes a reset condition. As the supply voltage rises, the LVD circuit holds the chip in reset until the supply has risen above the level determined by LVDV bit. Both the POR bit and the LVD bit in SRS are set following a POR.

Table 15. Power-on reset

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
t_R	Power on reset (POR)	V_{DD} risetime to avoid latch up	—	—	1	s	C
t_{POR}	Power on reset (POR)	Time for V_{DD} < 0.5 V to assure POR	70	—	—	µs	C
V_{PORR}	Power on reset (POR)	Rising voltage to release reset	—	—	2.1	V	C
V_{PORA}	Power on reset (POR)	Falling voltage to assert reset	0.8	—	—	V	C

6.6 GPIO port pins

Table 16. GPIO port pins

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
V_{OH}	Output high voltage	I_{LOAD} = 5 mA	V_{DD} – 0.35	—	—	V	D
V_{OL}	Output low voltage	I_{LOAD} = 5 mA	—	—	V_{SS} + 0.35	V	D
V_{IHn}	Input high voltage	2.3 V ≤ V_{DD} ≤ V_H, T_A = T_L, T_H	0.7 × V_{DD} / V_{DDA}	—	V_{DD} / V_{DDA}	V	D
V_{IHlv}	Input high voltage	V_{DD} ≤ 2.3 V, T_A = 25 °C	0.85 × V_{DD} / V_{DDA}	—	V_{DD} / V_{DDA}	V	D
V_{ILn}	Input low voltage	2.3 V ≤ V_{DD} ≤ V_H, T_A = T_L, T_H	V_{SS}	—	0.35 × V_{DD} / V_{DDA}	V	D
V_{ILlv}	Input low voltage	V_{DD} ≤ 2.3 V, T_A = 25 °C	V_{SS}	—	0.28 × V_{DD} / V_{DDA}	V	D
I_{IH}	Input high current, PTA0:3	Pulldown disabled; V_{IH} Min	–1	—	+1	µA	D
I_{IHp}	Input high current, PTA0:3	Pulldown enabled; V_{IH} Min	0	—	120	µA	D
I_{IL}	Input low current, PTA0:3	Pullup disabled; V_{IL} Max	–1	—	+1	µA	D
I_{ILp}	Input low current, PTA0:3	Pullup enabled; V_{IL} Max	–120	—	0	µA	D
I_{IH-IL}	Input current PTA4 only	V_{IH} Min and V_{IL} Max	–120	—	120	µA	D

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Table 16. GPIO port pins...*continued*

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
C_{IO}	Pin capacitance	V_{DD} = 3.0 V	0	—	15	pF	D
C_{MISO}	MISO load capacitance	V_{DD} = 3.0 V	—	—	50	pF	D

6.7 SPI timing characteristics

Table 17. SPI timing

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
t_{SSMIN}	SS_B asserted period	—	1	—	—	f_{BUS} period	D
t_{ACCESS}	SS_B low to MISO	—	—	—	50	ns	D
t_{LEAD}	SS_B low to SCLK start	—	50	—	—	ns	D
t_{SETUP}	MOSI to SCLK start	—	20	—	—	ns	D
t_{SCLK}	SCLK period	—	100	—	—	ns	D
t_{SCLKH}	SCLK high portion	—	35	—	—	ns	D
t_{SCLKL}	SCLK low portion	—	35	—	—	ns	D
t_{SCLKR}	SCLK risetime	—	—	10	25	ns	D
t_{SCLKF}	SCLK fall time	—	—	10	25	ns	D
t_{VALID}	MISO valid transition time	—	—	—	30	ns	D
t_{HOLD_IN}	MOSI hold time	—	10	—	—	ns	D
t_{HOLD_OUT}	SCLK high to MISO transition start	—	0	—	—	ns	D
t_{LAG}	Final SCLK low to SS_B high	—	60	—	—	ns	D
$t_{DISABLE}$	SS_B high to MISO 3-state	—	—	—	60	ns	D
t_{SS_REJ}	SS_B noise rejection period	—	—	—	5	ns	D
t_{SSCLK}	SS_B high to SCLK high	—	50	—	—	ns	D
t_{CLKSS}	SCLK high to SCLK low	—	50	—	—	ns	D
t_{SSN}	SS_B not asserted period	—	6	—	—	f_{BUS} period	D
$t_{LEAD-WU}$	Wake-up by SS_B low to SCLK start	—	1	—	—	ms	D
t_{SPI_EN}	SPI enable by SS_B low after V_{DD} > V_{PORR}	—	200	—	—	µs	D

6.8 Temperature measurement characteristics

Table 18. Temperature measurement

V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer function: T °C = (1 °C / LSB × T_{CODE}) – 55 °C

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
$DT_{MAX-MIN}$	Sensitivity	—	0.93	1	1.08	°C / LSB	C
T_{ERROR}	Error	—	—	0	—	LSB	C
T_{UNDER}	Underflow	—	—	1	—	LSB	C

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Table 18. Temperature measurement...*continued*

V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer function: T °C = (1 °C / LSB × T_{CODE}) – 55 °C

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
T_{OVER}	Overflow	—	—	255	—	LSB	C
T_{MIN}	Temperature measurement	T_A = –50 °C	—	5	—	LSB	D
$T_{RATE-MIN}$	Temperature measurement	T_A = –40 °C	11	15	19	LSB	C
T_{CODE}	Temperature measurement	T_A = –20 °C	32	35	38	LSB	A
T_{CODE}	Temperature measurement	T_A = 0 °C	52	55	58	LSB	C
T_{CODE}	Temperature measurement	T_A = 25 °C	77	80	83	LSB	B
T_{CODE}	Temperature measurement	T_A = 70 °C	122	125	128	LSB	C
T_{CODE}	Temperature measurement	T_A = 85 °C	137	140	143	LSB	A
T_{CODE}	Temperature measurement	T_A = 105 °C	156	160	164	LSB	C
$T_{RATE-MAX}$	Temperature measurement	T_A = 125 °C	175	180	185	LSB	B
T_{MAX}	Temperature measurement	T_A = 150 °C [1]	—	205	—	LSB	D
T_{DRIFT}	Temperature measurement drift	—	–3	—	+3	LSB	C

[1] Temperature excursions, time at T_{MAX} must not exceed 12 events of 15 minutes duration during the product lifetime.

6.9 Voltage measurement characteristics

Table 19. Voltage measurement characteristics

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer function: V = (0.01 V / LSB × V_{CODE}) + 1.22 V
Interpolated limits between –40 °C to 0 °C and between 50 °C to 125 °C.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
$DV_{MAX-MIN}$	Sensitivity	—	9	10	12	mV / LSB	C
V_{ERROR}	Error	—	—	0	—	LSB	C
V_{UNDER}	Underflow	—	—	1	—	LSB	C
V_{OVER}	Overflow	—	—	255	—	LSB	C
V_{CODE}	V_{DD} voltage, 2.8 V	0 °C ≤ T_A ≤ 50 °C, V_{DD} = 2.8 V	153	158	163	LSB	C
V_{CODE}	V_{DD} voltage, 3.0 V	0 °C ≤ T_A ≤ 50 °C, V_{DD} = 3.0 V	173	178	183	LSB	C
V_{CODE}	V_{DD} voltage, 3.3 V	0 °C ≤ T_A ≤ 50 °C, V_{DD} = 3.3 V	203	208	213	LSB	C
V_{MIN}	V_{DD} voltage, 1.8 V	—	38	58	78	LSB	C
V_{CODE}	V_{DD} voltage, 2.1 V	—	68	88	108	LSB	B
V_{CODE}	V_{DD} voltage, 2.3 V	–40 °C ≤ T_A ≤ 0 °C or 50 °C ≤ T_A ≤ 125 °C, V_{DD} = 2.3 V	98	108	118	LSB	C
V_{CODE}	V_{DD} voltage, 2.8 V	–40 °C ≤ T_A ≤ 0 °C or 50 °C ≤ T_A ≤ 125 °C, V_{DD} = 2.8 V	148	158	168	LSB	C
V_{CODE}	V_{DD} voltage, 3.0 V	–40 °C ≤ T_A ≤ 0 °C or 50 °C ≤ T_A ≤ 125 °C, V_{DD} = 3.0 V	168	178	188	LSB	B
V_{CODE}	V_{DD} voltage, 3.3 V	–40 °C ≤ T_A ≤ 0 °C or 50 °C ≤ T_A ≤ 125 °C, V_{DD} = 3.3 V	198	208	218	LSB	C
V_{MAX}	V_{DD} voltage, 3.6 V	—	228	238	248	LSB	C
V_{DRIFT}	Voltage drift	—	–3	—	+3	LSB	C

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Table 20. External pin voltage measurement

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer function: V = (V_{DD} V / LSB × GxCODE) / 1023, where x = 0 for PTB0, 1 for PTB1

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
ΔGxMAX-MIN	Sensitivity	—	—	V_{dd} / 1023	—	V / LSB	C
GxERROR	Error	Status = $01	—	0	—	LSB	C
GxCODE	Voltage measurement, V = 0 V	Status = $00	—	0	—	LSB	C
GxCODE	Voltage measurement, V = VDD V	—	—	1023	—	LSB	C
GxDRIFT	Voltage measurement drift	—	–1	—	+1	LSB	C

6.10 Pressure measurement characteristics

Unless otherwise noted, stated tolerances are valid only with Initial Sample Delay [ISD3:0] set for > 2.5 ms and MCU placed in STOP4 mode.

6.10.1 Pressure measurement characteristic (90 kPa to 930 kPa) range

Table 21. Pressure measurement characteristics (90 kPa to 930 kPa) range

V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer function: P kPa = (0.824 kPa / LSB × P_{CODE}) + 88.353 kPa
Interpolated limits between 105 °C and 125 °C.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
$DP_{MAX-MIN}$	Sensitivity	—	0.78	0.824	0.86	kPa / LSB	C
P_{ERROR}	Error	—	—	0	—	LSB	C
P_{UNDER}	Underflow	FW error status bit 0 = 1	—	1	—	LSB	C
P_{OVER}	Overflow	FW error status bit 0 = 1	—	1023	—	LSB	C
P_{MIN}	Proof pressure, 90 kPa	–40 °C ≤ T_A ≤ 105 °C	—	2	11	LSB	D
P_{CODE}	Proof pressure, 230 kPa	–40 °C ≤ T_A ≤ 105 °C	166	172	178	LSB	C
P_{CODE}	Proof pressure, 370 kPa	–40 °C ≤ T_A ≤ 105 °C	336	342	348	LSB	A
P_{CODE}	Proof pressure, 510 kPa	–40 °C ≤ T_A ≤ 105 °C	506	512	518	LSB	C
P_{CODE}	Proof pressure, 650 kPa	–40 °C ≤ T_A ≤ 105 °C	676	682	688	LSB	C
P_{CODE}	Proof pressure, 790 kPa	–40 °C ≤ T_A ≤ 105 °C	846	852	858	LSB	A
P_{MAX}	Proof pressure, 930 kPa	–40 °C ≤ T_A ≤ 105 °C	1016	1022	—	LSB	D
P_{MIN}	Proof pressure, 90 kPa	T_A = 125 °C	—	2	22	LSB	D
P_{CODE}	Proof pressure, 230 kPa	T_A = 125 °C	151	172	192	LSB	C
P_{CODE}	Proof pressure, 370 kPa	T_A = 125 °C	322	342	362	LSB	C
P_{CODE}	Proof pressure, 510 kPa	T_A = 125 °C	492	512	532	LSB	C
P_{CODE}	Proof pressure, 650 kPa	T_A = 125 °C	662	682	702	LSB	C
P_{CODE}	Proof pressure, 790 kPa	T_A = 125 °C	832	852	872	LSB	C
P_{MAX}	Proof pressure, 930 kPa	T_A = 125 °C	1002	1022	—	LSB	D
P_{DRIFT}	Pressure drift	—	—	—	±6	LSB	C

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6.11 Acceleration measurement characteristics

Unless otherwise noted, stated tolerances are valid only with Initial Sample Delay [ISD3:0] set for > 2.5 ms and MCU placed in STOP4 mode.

6.11.1 Acceleration measurement characteristics (–80 g to +90 g) range option

Table 22. Acceleration measurement characteristic (–80 g to +90 g) range option

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer Function: Offset Step 7 A g's = (0.020 g/LSB × A_{CODE}) – 10.039 g
Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
$DA_{MAX-MIN}$	Sensitivity	—	0.014	0.020	0.034	g / LSB	C
A_{ERROR}	Error	—	—	0	—	LSB	C
A_{UNDER}	Underflow	FW error status bit 0 = 1	—	1	—	LSB	C
A_{OVER}	Overflow	FW error status bit 0 = 1	—	1023	—	LSB	C
A_{MIN0}	Acceleration measurement, –80 g, Offset step 0	–20 °C ≤ T_A ≤ 85 °C	—	2	—	LSB	D
A_{CODE0}	Acceleration measurement, –75 g, Offset Step 0	–20 °C ≤ T_A ≤ 85 °C	—	257	—	LSB	D
A_{CODE0}	Acceleration measurement, –70 g, Offset Step 0	–20 °C ≤ T_A ≤ 85 °C	—	512	—	LSB	D
A_{CODE0}	Acceleration measurement, –65 g, Offset Step 0	–20 °C ≤ T_A ≤ 85 °C	—	767	—	LSB	D
A_{MAX0}	Acceleration measurement, –60 g, Offset Step 0	–20 °C ≤ T_A ≤ 85 °C	—	1022	—	LSB	D
A_{MIN7}	Acceleration measurement, –10 g, Offset Step 7	–20 °C ≤ T_A ≤ 85 °C	—	2	180	LSB	D
A_{CODE7}	Acceleration measurement, –5 g, Offset Step 7	–20 °C ≤ T_A ≤ 85 °C	104	257	410	LSB	D
A_{CODE7}	Acceleration measurement, 0 g, Offset Step 7	–20 °C ≤ T_A ≤ 85 °C	384	512	640	LSB	A
A_{CODE7}	Acceleration measurement, 5 g, Offset Step 7	–20 °C ≤ T_A ≤ 85 °C	614	767	920	LSB	D
A_{MAX7}	Acceleration measurement, 10 g, Offset Step 7	–20 °C ≤ T_A ≤ 85 °C	844	1022	—	LSB	D
A_{MIN7}	Acceleration measurement, –10 g, Offset Step 7	T_A = –40 °C and 125 °C	—	2	216	LSB	D
A_{CODE7}	Acceleration measurement, –5 g, Offset Step 7	T_A = –40 °C and 125 °C	73	257	441	LSB	D
A_{CODE7}	Acceleration measurement, 0 g, Offset Step 7	T_A = –40 °C and 125 °C	359	512	665	LSB	D
A_{CODE7}	Acceleration measurement, 5 g, Offset Step 7	T_A = –40 °C and 125 °C	583	767	951	LSB	D
A_{MAX7}	Acceleration measurement, 10 g, Offset Step 7	T_A = –40 °C and 125 °C	808	1022	—	LSB	D
A_{MIN15}	Acceleration measurement, 70 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	2	—	LSB	D
A_{CODE15}	Acceleration measurement, 75 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	257	—	LSB	D

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Table 22. Acceleration measurement characteristic (–80 g to +90 g) range option...*continued*

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer Function: Offset Step 7 A g's = (0.020 g/LSB × A_{CODE}) – 10.039 g
Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
A_{CODE15}	Acceleration measurement, 80 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	512	—	LSB	D
A_{CODE15}	Acceleration measurement, 85 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	767	—	LSB	D
A_{MAX15}	Acceleration measurement, 90 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	1022	—	LSB	D
A_{DRIFT}	Inertia drift	—	–5	—	+5	LSB	C

6.11.2 Acceleration measurement characteristic (–360 g to +400 g) range option

Table 23. Acceleration measurement characteristic (–360 g to +400 g) range option

V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer Function: Offset Step 7 A g's = (0.088 g/LSB × A_{CODE}) – 45.176 g
Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
$DdrA_{MAX-MIN}$	Sensitivity	—	0.074	0.088	0.108	g / LSB	C
A_{ERROR}	Error	—	—	0	—	LSB	C
A_{UNDER}	Underflow	FW error status bit 0 = 1	—	1	—	LSB	C
A_{OVER}	Overflow	FW error status bit 0 = 1	—	1023	—	LSB	C
A_{MIN0}	Acceleration measurement, –360 g, Offset step 0	–20 °C ≤ T_A ≤ 85 °C	—	2	—	LSB	D
A_{CODE0}	Acceleration measurement, –338 g, Offset step 0	–20 °C ≤ T_A ≤ 85 °C	—	257	—	LSB	D
A_{CODE0}	Acceleration measurement, –315 g, Offset step 0	–20 °C ≤ T_A ≤ 85 °C	—	512	—	LSB	D
A_{CODE0}	Acceleration measurement, –293 g, Offset step 0	–20 °C ≤ T_A ≤ 85 °C	—	767	—	LSB	D
A_{MAX0}	Acceleration measurement, –270 g, Offset step 0	–20 °C ≤ T_A ≤ 85 °C	—	1022	—	LSB	D
A_{MIN7}	Acceleration measurement, –45 g, Offset step 7	–20 °C ≤ T_A ≤ 85 °C	—	2	81	LSB	D
A_{CODE7}	Acceleration measurement, –22.5 g, Offset step 7	–20 °C ≤ T_A ≤ 85 °C	203	257	311	LSB	D
A_{CODE7}	Acceleration measurement, 0 g, Offset step 7	–20 °C ≤ T_A ≤ 85 °C	483	512	541	LSB	A
A_{CODE7}	Acceleration measurement, 22.5 g, Offset step 7	–20 °C ≤ T_A ≤ 85 °C	713	767	821	LSB	D
A_{MAX7}	Acceleration measurement, 45 g, Offset step 7	–20 °C ≤ T_A ≤ 85 °C	943	1022	—	LSB	D
A_{MIN7}	Acceleration measurement, –45 g, Offset step 7	T_A = –40 °C and 125 °C	—	2	97	LSB	D
A_{CODE7}	Acceleration measurement, –22.5 g, Offset step 7	T_A = –40 °C and 125 °C	192	257	322	LSB	D

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Table 23. Acceleration measurement characteristic (–360 g to +400 g) range option...*continued*

V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer Function: Offset Step 7 A g's = (0.088 g/LSB × A_{CODE}) – 45.176 g
Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
A_{CODE7}	Acceleration measurement, 0 g, Offset step 7	T_A = –40 °C and 125 °C	478	512	546	LSB	D
A_{CODE7}	Acceleration measurement, 22.5 g, Offset step 7	T_A = –40 °C and 125 °C	702	767	832	LSB	D
A_{MAX7}	Acceleration measurement, 45 g, Offset step 7	T_A = –40 °C and 125 °C	927	1022	—	LSB	D
A_{MIN15}	Acceleration measurement, 315 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	2	—	LSB	D
A_{CODE15}	Acceleration measurement, 338 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	257	—	LSB	D
A_{CODE15}	Acceleration measurement, 360 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	512	—	LSB	D
A_{CODE15}	Acceleration measurement, 383 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	767	—	LSB	D
A_{MAX15}	Acceleration measurement, 405 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	1022	—	LSB	D
A_{DRIFT}	Acceleration measurement drift	—	–4	—	+4	LSB	C

6.11.3 Acceleration measurement characteristic (–120 g to +520 g) range option

Table 24. Acceleration measurement characteristic (–120 g to +520 g) range option

V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer Function: Offset Step 2 A g's = (0.102 g/LSB × A_{CODE}) – 52.204 g
Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
$DA_{MAX-MIN}$	Sensitivity	—	0.087	0.102	0.124	g / LSB	C
A_{ERROR}	Error	—	—	0	—	LSB	C
A_{UNDER}	Underflow	FW error status bit 0 = 1	—	1	—	LSB	C
A_{OVER}	Overflow	FW error status bit 0 = 1	—	1023	—	LSB	C
A_{MIN0}	Acceleration measurement, –124 g, Offset step 0	–20 °C ≤ T_A ≤ 85 °C	—	2	—	LSB	D
A_{CODE0}	Acceleration measurement, –98 g, Offset step 0	–20 °C ≤ T_A ≤ 85 °C	—	257	—	LSB	D
A_{CODE0}	Acceleration measurement, –72 g, Offset step 0	–20 °C ≤ T_A ≤ 85 °C	—	512	—	LSB	D
A_{CODE0}	Acceleration measurement, –46 g, Offset step 0	–20 °C ≤ T_A ≤ 85 °C	—	767	—	LSB	D
A_{MAX0}	Acceleration measurement, –20 g, Offset step 0	–20 °C ≤ T_A ≤ 85 °C	—	1022	—	LSB	D
A_{MIN2}	Acceleration measurement, –52 g, Offset step 2	–20 °C ≤ T_A ≤ 85 °C	—	2	77	LSB	D
A_{CODE2}	Acceleration measurement, –26 g, Offset step 2	–20 °C ≤ T_A ≤ 85 °C	207	257	307	LSB	D

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Table 24. Acceleration measurement characteristic (–120 g to +520 g) range option...*continued*

V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer Function: Offset Step 2 A g's = (0.102 g/LSB × A_{CODE}) – 52.204 g
Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
A_{CODE2}	Acceleration measurement, 0 g, Offset step 2	–20 °C ≤ T_A ≤ 85 °C	487	512	537	LSB	A
A_{CODE2}	Acceleration measurement, 26 g, Offset step 2	–20 °C ≤ T_A ≤ 85 °C	717	767	817	LSB	D
A_{MAX2}	Acceleration measurement, 52 g, Offset step 2	–20 °C ≤ T_A ≤ 85 °C	947	1022	—	LSB	D
A_{MIN2}	Acceleration measurement, –52 g, Offset step 2	T_A = –40 °C and 125 °C	—	2	92	LSB	D
A_{CODE2}	Acceleration measurement, –26 g, Offset step 2	T_A = –40 °C and 125 °C	197	257	317	LSB	D
A_{CODE2}	Acceleration measurement, 0 g, Offset step 2	T_A = –40 °C and 125 °C	482	512	542	LSB	D
A_{CODE2}	Acceleration measurement, 26 g, Offset step 2	T_A = –40 °C and 125 °C	707	767	827	LSB	D
A_{MAX2}	Acceleration measurement, 52 g, Offset step 2	T_A = –40 °C and 125 °C	932	1022	1112	LSB	D
A_{MIN15}	Acceleration measurement, 416 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	2	—	LSB	D
A_{CODE15}	Acceleration measurement, 442 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	257	—	LSB	D
A_{CODE15}	Acceleration measurement, 468 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	512	—	LSB	D
A_{CODE15}	Acceleration measurement, 494 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	767	—	LSB	D
A_{MAX15}	Acceleration measurement, 520 g, Offset Step 15	–20 °C ≤ T_A ≤ 85 °C	—	1022	—	LSB	D
A_{DRIFT}	Acceleration measurement drift	—	–4	—	+4	LSB	C

6.11.4 Acceleration measurement characteristic (–175 g to +550 g) range option

Table 25. Acceleration measurement characteristic (–175 g to +550 g) range option

V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer Function: Offset Step 7 A g's = (0.343 g/LSB × A_{CODE}) – 175.686 g
Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C
Due to the inverted polarity calibration where the offset steps are in reverse order, the standard library function TPMS_READ_DYNAMIC_ACCEL is not compatible with this range option.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
$\Delta A_{MAX-MIN}$	Sensitivity		0.302	0.343	0.398	g / LSB	C
A_{ERROR}	Error			0		LSB	C
A_{UNDER}	Underflow	FW error status bit 0 = 1		1		LSB	C
A_{OVER}	Overflow	FW error status bit 0 = 1		1023		LSB	C
A_{MIN4}	Acceleration measurement, 200 g, Offset step 4	-20 °C ≤ TA ≤ 85 °C	—	2	—	LSB	D
A_{CODE4}	Acceleration measurement, 288 g, Offset step 4	-20 °C ≤ TA ≤ 85 °C	—	257	—	LSB	D

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Table 25. Acceleration measurement characteristic (–175 g to +550 g) range option*...continued*

V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer Function: Offset Step 7 A g's = (0.343 g/LSB × A_{CODE}) – 175.686 g
Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C
Due to the inverted polarity calibration where the offset steps are in reverse order, the standard library function TPMS_READ_DYNAMIC_ACCEL is not compatible with this range option.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
$A_{CODE}4$	Acceleration measurement, 375 g, Offset step 4	-20 °C ≤ TA ≤ 85 °C	—	512	—	LSB	D
$A_{CODE}4$	Acceleration measurement, 463 g, Offset step 4	-20 °C ≤ TA ≤ 85 °C	—	767	—	LSB	D
$A_{MAX}4$	Acceleration measurement, 550 g, Offset step 4	-20 °C ≤ TA ≤ 85 °C	—	1022	—	LSB	D
$A_{MIN}5$	Acceleration measurement, 75 g, Offset step 5	-20 °C ≤ TA ≤ 85 °C	—	2	—	LSB	D
$A_{CODE}5$	Acceleration measurement, 163 g, Offset step 5	-20 °C ≤ TA ≤ 85 °C	—	257	—	LSB	D
$A_{CODE}5$	Acceleration measurement, 250 g, Offset step 5	-20 °C ≤ TA ≤ 85 °C	—	512	—	LSB	D
$A_{CODE}5$	Acceleration measurement, 338 g, Offset step 5	-20 °C ≤ TA ≤ 85 °C	—	767	—	LSB	D
$A_{MAX}5$	Acceleration measurement, 425 g, Offset step 5	-20 °C ≤ TA ≤ 85 °C	—	1022	—	LSB	D
$A_{MIN}6$	Acceleration measurement, -50 g, Offset step 6	-20 °C ≤ TA ≤ 85 °C	—	2	—	LSB	D
$A_{CODE}6$	Acceleration measurement, 38 g, Offset step 6	-20 °C ≤ TA ≤ 85 °C	—	257	—	LSB	D
ACODE6	Acceleration measurement, 125 g, Offset step 6	-20 °C ≤ TA ≤ 85 °C	—	512	—	LSB	D
$A_{CODE}6$	Acceleration measurement, 213 g, Offset step 6	-20 °C ≤ TA ≤ 85 °C	—	767	—	LSB	D
$A_{MAX}6$	Acceleration measurement, 300 g, Offset step 6	-20 °C ≤ TA ≤ 85 °C	—	1022	—	LSB	D
A_{MIN} 7	Acceleration measurement, –175 g, Offset step 7	-20 °C ≤ TA ≤ 85 °C	—	2	60	LSB	D
A_{CODE} 7	Acceleration measurement, –88 g, Offset step 7	-20 °C ≤ TA ≤ 85 °C	224	257	290	LSB	D
A_{CODE} 7	Acceleration measurement, 0 g, Offset step 7	-20 °C ≤ TA ≤ 85 °C	504	512	520	LSB	A
A_{CODE} 7	Acceleration measurement, 88 g, Offset step 7	-20 °C ≤ TA ≤ 85 °C	734	767	800	LSB	D
A_{MAX} 7	Acceleration measurement, 175 g, Offset step 7	-20 °C ≤ TA ≤ 85 °C	964	1022	—	LSB	D
A_{MIN} 7	Acceleration measurement, –175 g, Offset step 7	TA = -40 °C & 125 °C	—	2	72	LSB	D
A_{CODE} 7	Acceleration measurement, –88 g, Offset step 7	TA = -40 °C & 125 °C	218	257	296	LSB	D
A_{CODE} 7	Acceleration measurement, 0 g, Offset step 7	TA = -40 °C & 125 °C	503	512	525	LSB	D
A_{CODE} 7	Acceleration measurement, 88 g, Offset step 7	TA = -40 °C & 125 °C	728	767	806	LSB	D

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Table 25. Acceleration measurement characteristic (–175 g to +550 g) range option...*continued*

V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer Function: Offset Step 7 A g's = (0.343 g/LSB × A_{CODE}) – 175.686 g
Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C
Due to the inverted polarity calibration where the offset steps are in reverse order, the standard library function TPMS_READ_DYNAMIC_ACCEL is not compatible with this range option.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
A_{MAX} 7	Acceleration measurement, 175 g, Offset step 7	TA = -40 °C & 125 °C	952	1022	—	LSB	D
A_{MIN} 8	Acceleration measurement, –300 g, Offset step 8	-20 °C ≤ TA ≤ 85 °C	—	2	—	LSB	D
A_{CODE} 8	Acceleration measurement, –213 g, Offset step 8	-20 °C ≤ TA ≤ 85 °C	—	257	—	LSB	D
A_{CODE} 8	Acceleration measurement, –125 g, Offset step 8	-20 °C ≤ TA ≤ 85 °C	—	512	—	LSB	D
A_{CODE} 8	Acceleration measurement, –38 g, Offset step 8	-20 °C ≤ TA ≤ 85 °C	—	767	—	LSB	D
A_{MAX} 8	Acceleration measurement, 50 g, Offset step 8	-20 °C ≤ TA ≤ 85 °C	—	1022	—	LSB	D
A_{MIN} 9	Acceleration measurement, –425 g, Offset step 9	-20 °C ≤ TA ≤ 85 °C	—	2	—	LSB	D
A_{CODE} 9	Acceleration measurement, –338 g, Offset step 9	-20 °C ≤ TA ≤ 85 °C	—	257	—	LSB	D
A_{CODE} 9	Acceleration measurement, –250 g, Offset step 9	-20 °C ≤ TA ≤ 85 °C	—	512	—	LSB	D
A_{CODE} 9	Acceleration measurement, –163 g, Offset step 9	-20 °C ≤ TA ≤ 85 °C	—	767	—	LSB	D
A_{MAX} 9	Acceleration measurement, –75 g, Offset step 9	-20 °C ≤ TA ≤ 85 °C	—	1022	—	LSB	D
A_{MIN} 10	Acceleration measurement, –550 g, Offset step 10	-20 °C ≤ TA ≤ 85 °C	—	2	—	LSB	D
A_{CODE} 10	Acceleration measurement, –463 g, Offset step 10	-20 °C ≤ TA ≤ 85 °C	—	257	—	LSB	D
A_{CODE} 10	Acceleration measurement, –375 g, Offset step 10	-20 °C ≤ TA ≤ 85 °C	—	512	—	LSB	D
A_{CODE} 10	Acceleration measurement, –288 g, Offset step 10	-20 °C ≤ TA ≤ 85 °C	—	767	—	LSB	D
A_{MAX} 10	Acceleration measurement, –200 g, Offset step 10	-20 °C ≤ TA ≤ 85 °C	—	1022	—	LSB	D
A_{DRIFT}	Inertia drift		–4		+4	LSB	C

6.11.5 Acceleration measurement characteristic (–400 g to +400 g) range option

Table 26. Acceleration measurement characteristic (–400 g to +400 g) range option

V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer Function: Offset Step 7 A g's = (0.294 g/LSB × A_{CODE}) – 150.59 g
Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
$\Delta A_{MAX\text{-}MIN}$	Sensitivity		0.260	0.294	0.342	g / LSB	C
A_{ERROR}	Error			0		LSB	C

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Table 26. Acceleration measurement characteristic (–400 g to +400 g) range option...*continued*

V_{DDM} Min ≤ V_{DD} ≤ V_{DDM} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
Transfer Function: Offset Step 7 A g's = (0.294 g/LSB × A_{CODE}) – 150.59 g
Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
A_{UNDER}	Underflow	FW error status bit 0 = 1		1		LSB	C
A_{OVER}	Overflow	FW error status bit 0 = 1		1023		LSB	C
A_{MIN} 6	Acceleration measurement, –400 g, Offset step 6	-20 °C ≤ TA ≤ 85 °C	—	2	—	LSB	D
A_{CODE} 6	Acceleration measurement, –325 g, Offset step 6	-20 °C ≤ TA ≤ 85 °C	—	257	—	LSB	D
A_{CODE} 6	Acceleration measurement, –250 g, Offset step 6	-20 °C ≤ TA ≤ 85 °C	—	512	—	LSB	D
A_{CODE} 6	Acceleration measurement, –175 g, Offset step 6	-20 °C ≤ TA ≤ 85 °C	—	767	—	LSB	D
A_{MAX} 6	Acceleration measurement, –100 g, Offset step 6	-20 °C ≤ TA ≤ 85 °C	—	1022	—	LSB	D
A_{MIN} 7	Acceleration measurement, –150 g, Offset step 7	-20 °C ≤ TA ≤ 85 °C	—	2	61	LSB	D
A_{CODE} 7	Acceleration measurement, –75 g, Offset step 7	-20 °C ≤ TA ≤ 85 °C	223	257	291	LSB	D
A_{CODE} 7	Acceleration measurement, 0 g, Offset step 7	-20 °C ≤ TA ≤ 85 °C	503	512	521	LSB	A
A_{CODE} 7	Acceleration measurement, 75 g, Offset step 7	-20 °C ≤ TA ≤ 85 °C	733	767	801	LSB	D
A_{MAX} 7	Acceleration measurement, 150 g, Offset step 7	-20 °C ≤ TA ≤ 85 °C	963	1022	—	LSB	D
A_{MIN} 7	Acceleration measurement, –150 g, Offset step 7	TA = -40 °C & 125 °C	—	2	73	LSB	D
A_{CODE} 7	Acceleration measurement, –75 g, Offset step 7	TA = -40 °C & 125 °C	216	257	298	LSB	D
A_{CODE} 7	Acceleration measurement, 0 g, Offset step 7	TA = -40 °C & 125 °C	501	512	523	LSB	D
A_{CODE} 7	Acceleration measurement, 75 g, Offset step 7	TA = -40 °C & 125 °C	726	767	808	LSB	D
A_{MAX} 7	Acceleration measurement, 150 g, Offset step 7	TA = -40 °C & 125 °C	951	1022	—	LSB	D
A_{MIN} 8	Acceleration measurement, 100 g, Offset step 8	-20 °C ≤ TA ≤ 85 °C	—	2	—	LSB	D
A_{CODE} 8	Acceleration measurement, 175 g, Offset step 8	-20 °C ≤ TA ≤ 85 °C	—	257	—	LSB	D
A_{CODE} 8	Acceleration measurement, 250 g, Offset step 8	-20 °C ≤ TA ≤ 85 °C	—	512	—	LSB	D
A_{CODE} 8	Acceleration measurement, 325 g, Offset step 8	-20 °C ≤ TA ≤ 85 °C	—	767	—	LSB	D
A_{MAX} 8	Acceleration measurement, 400 g, Offset step 8	-20 °C ≤ TA ≤ 85 °C	—	1022	—	LSB	D
A_{DRIFT}	Inertia drift		–5		+5	LSB	C

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6.12 Low frequency receiver characteristics

Table 27. LFR characteristics

V_{DDF} Min ≤ V_{DD} ≤ V_{DDF} Max, T_{AF} Min ≤ T_A ≤ T_{AF} Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
R_{LFDF}	LFA / LFB load resistance	—	0.8	—	4	MΩ	D
DR_{LFIN}	Dynamic range, f_C at BW_{ACC}	Data mode, always detect	56	—	—	dB	D
$V_{IN-AD-H}$	Sensitivity, high - carrier and data modes	Always detect	—	—	3.0	mVPP	B
$V_{IN-ND-H}$	Sensitivity, high - carrier and data modes	Never detect	0.25	—	—	mVPP	B
$V_{IN-AD-L}$	Sensitivity, low - carrier and data modes	Always detect	—	—	12.0	mVPP	B
$V_{IN-ND-L}$	Sensitivity, low - carrier and data modes	Never detect	4.0	—	—	mVPP	B
MD	Modulation depth	—	70	—	100	%	C
BRLF	Baud rate	—	3788	3906	4032	Bit/s	C
DCM	Manchester duty cycle tolerance	—	—	40 / 60	45 / 55	%	C
DCN	NRZ duty cycle tolerance	—	—	50 / 50	45 / 55	%	C
MER	Message error rate	—	—	5	—	%	C
BW_{ACC}	Bandwidth	Always detect	≥ 88	—	≤ 175	kHz	C
BW_{REJ}	Bandwidth	Never detect	< 88	—	> 175	kHz	C
t_{LF}	Signal rise / decay time constant, carrier envelope	—	15.3	—	—	µs	D

6.13 Radio frequency transmitter characteristics

Table 28. Radio frequency transmitter characteristics

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
All conditions characterized with NDK NX2016SA 26.000 MHz crystal.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
PRF3	Nominal output power w/ 50 Ω matching network	315 MHz, 25 °C, 3.0 V PWR[4:0] = 0 1 1 0 0	—	5	—	dBm	C
PRF4	Nominal output power w/ 50 Ω matching network	434 MHz, 25 °C, 3.0 V PWR[4:0] = 0 1 1 1 0	—	5	—	dBm	C
PRF	Output power, range	—	–1.5	—	8	dBm	C
PRFSTEP	Output power, step size	—	—	0.5	—	dBm	C
PRFMINp	Output power, minimum PRF vs. T_A and V_{DD} under control of FW TPMS_RF_DYNAMIC_POWER	-40 °C ≤ TA ≤ 0 °C and 1.8 V ≤ V_{DD} ≤ 2.5 V, or 0 °C ≤ T_A ≤ 125 °C and 2.5 V ≤ V_{DD} ≤ 3.6 V	3	—	—	dBm	C
PRFMINn	Output power, minimum PRF vs. T_A and V_{DD} under control of FW TPMS_RF_DYNAMIC_POWER	25 °C ≤ T_A ≤ 60 °C and 2.5 V ≤ V_{DD} ≤ 3.6 V	5	—	—	dBm	C
PRFMIN00	Output power, Step = 00	—	—	–10	—	dBm	C
FSK	Frequency shift key step	—	—	3.17	—	kHz	D

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Table 28. Radio frequency transmitter characteristics...*continued*

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
All conditions characterized with NDK NX2016SA 26.000 MHz crystal.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
MOOK	On off key modulation depth	—	60	80	—	dBc	C
BRRF	Baud rate range	—	1.2	—	38.4	kbits/sec	C
DR	Manchester encoding bit/s accuracy, based on MFO	—	–5	—	+5	%	D
DC	Modulation duty cycle, FSK, and OOK	—	45	50	55	%	C
FxTAL	External crystal frequency, all conditions	—	—	26	—	MHz	D
t_{S-RCTS}	Fixed portion, RF start-up process	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	500	620	µs	C
Bits	Variable portion, RF start-up process	—	—	3	—	bit times	C
tRF2	Total RF start time, write of SEND bit to start of RF output, at 2000 bit/s, where tRF = tS-RCTS + (Bits * bit/s^–1	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	2	2.2	ms	C
tRF9	Total RF start time, write of SEND bit to start of RF output, at 9600 bit/s, where tRF = tS-RCTS + (Bits * bit/s^–1	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	800	920	µs	C
tRF20	Total RF start time, write of SEND bit to start of RF output, at 20000 bit/s, where tRF = tS-RCTS + (Bits * bit/s^–1	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	640	760	µs	C
H2	Harmonic 2, 315 MHz or 434 MHz, with 50 Ω matching network, power step adjusted to reach target power in each domain.	—	—	—	–22	dBc	C
H3	Harmonic 3, 315 MHz or 434 MHz, with 50 Ω matching network, power step adjusted to reach target power in each domain.	—	—	—	–31	dBc	C
H4	Harmonic 4, 315 MHz or 434 MHz, with 50 Ω matching network, power step adjusted to reach target power in each domain.	—	—	—	–40	dBc	C
N3PH10k	315 MHz phase noise, ±10 kHz, Boost = 0	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	–87	–78	dBc / Hz	C
N3PH100k	315 MHz phase noise, ±100 kHz, Boost = 0	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	–95	–87	dBc / Hz	C
N3PH1M	315 MHz phase noise, ±1 MHz, Boost = 0	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	–82	–77	dBc / Hz	C
N31PH10k	315 MHz phase noise, ±10 kHz, Boost = 1	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	–75	–66	dBc / Hz	C
N31PH100k	315 MHz phase noise, ±100 kHz, Boost = 1	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	–83	–75	dBc / Hz	C
N31PH1M	315 MHz phase noise, ±1 MHz, Boost = 1	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	–96	–93	dBc / Hz	C

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Table 28. Radio frequency transmitter characteristics...*continued*

V_{DDS} Min ≤ V_{DD} ≤ V_{DDS} Max, T_{AS} Min ≤ T_A ≤ T_{AS} Max, unless otherwise specified.
All conditions characterized with NDK NX2016SA 26.000 MHz crystal.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
N4PH10k	434 MHz phase noise, ±10 kHz, Boost = 0	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	–85	–75	dBc / Hz	C
N4PH100k	434 MHz phase noise, ±100 kHz, Boost = 0	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	–92	–83	dBc / Hz	C
N4PH1M	434 MHz phase noise, ±1 MHz, Boost = 0	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	–83	–78	dBc / Hz	C
NPH10M	Phase noise, ±10 MHz	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	–105	–101	dBc / Hz	C
NSP315	Spurious noise, <1 GHz, 10 kHz BW 315 MHz FCC 15.231a–e	—	—	—	–30	dBc	C
NSPUG	Spurious noise, < 1 GHz, 10 kHz BW 434 MHz ETSI EN300220	—	—	—	–40	dBc	C
NSPOG	Spurious noise, >1 GHz, 10 kHz BW 434 MHz ETSI EN300220	—	—	—	–40	dBc	C
OBWKF	Occupied bandwidth, < ±35 kHz FSK up to 19.2 kbit/s Korea, MIC 2007-63	—	—	—	200	kHz	C
OBWKO	Occupied bandwidth, OOK up to 9.6 kbit/s, Korea, MIC 2007-64	—	—	—	200	kHz	C
OBWJF	Occupied bandwidth, < ±45 kHz FSK up to 38.4 kbit/s, Japan, ARIB STD-T93	—	—	—	400	kHz	C
OBWJO	Occupied bandwidth, OOK up to 19.2 kbit/s, Japan, ARIB STD-T94	—	—	—	600	kHz	C
ML	Oscillation margin	—	850	—	—	Ω	D
f_{XCO}	Internal oscillator accuracy	—	–10	—	+10	ppm	D
v_{AREGOK}	RF V_{reg} capacitor Pre-charge voltage - Note: 0.47 µF V_{reg} capacitor connected.	V_{DDS} ≥ 2.1 V	—	1.5	—	V	C
t_{AREGOK}	RF V_{reg} capacitor Pre-charge Process - Note: 0.47 µF V_{reg} capacitor connected, additional to $t_{S\text{-}RCTS}$	V_{DDS} ≥ 2.1 V	—	630	1000	µSec	D

The firmware routine TPMS_PRECHARGE_EN performs the pre-charge of RF V_{reg} capacitor. When the pre-charge is successful, the execution time of the routine corresponds to t_{AREGOK} duration. When the pre-charge fails, the routine exits after a timeout longer than t_{AREGOK} max duration.

6.14 Power consumption RF transmissions

Using the TPMS_RF_DYNAMIC_POWER firmware routine[2] allows adjusting the power step in order to compensate for variations of output power versus temperature and voltage. This routine is associated to a part-to-part trimming that initially adjusts the power step to compensate for process variations.

2 Refer to user manual, UM11227.[1]

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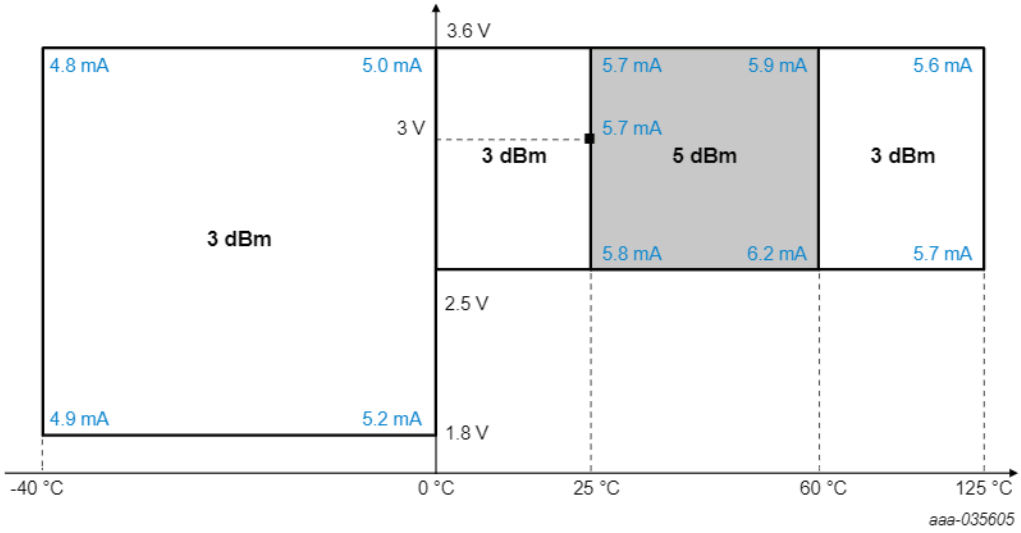


Figure 4. Dynamic power adjustment — 315 MHz

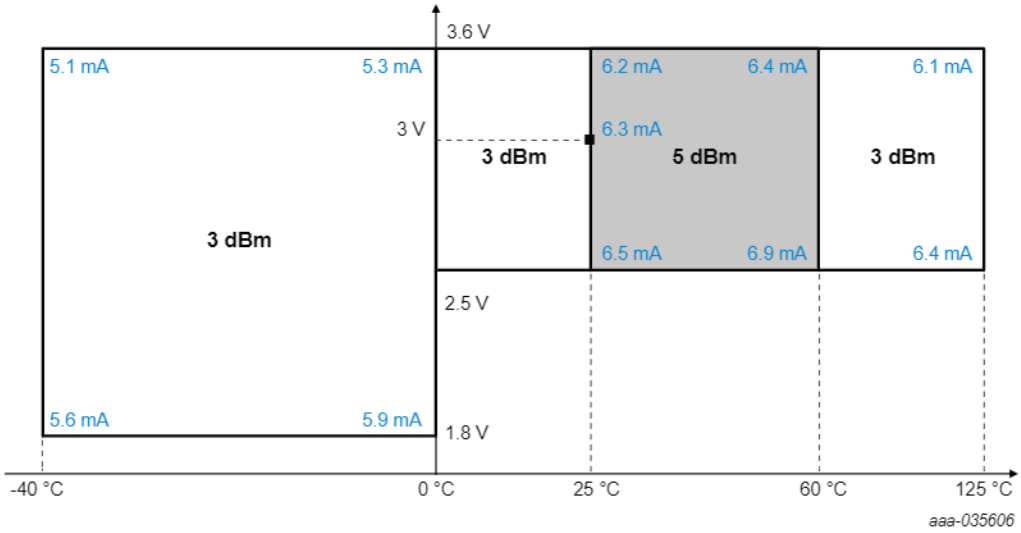


Figure 5. Dynamic power adjustment — 434 MHz

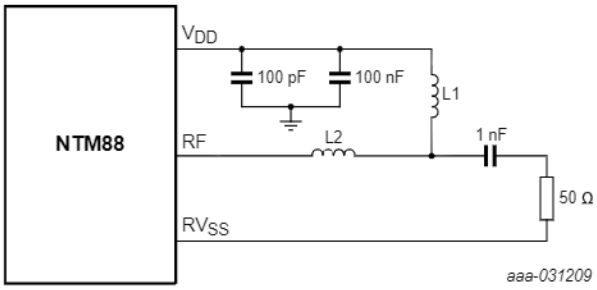


Figure 6. RF output power measurement configuration

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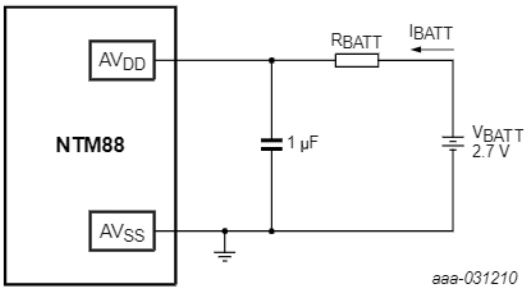


Figure 7. Battery performance test configuration

7 Mechanical specifications

7.1 Maximum ratings (mechanical)

Maximum ratings are the extreme limits the device can be exposed without permanent damage. The device contains circuitry to protect the inputs against damage from high static voltages; however, do not apply voltages higher than the values shown in Table 29. Keep V_{IN} and V_{OUT} within the range $V_{SS} \le (V_{IN}$ or $V_{OUT}) \le V_{DD}$.

Table 29. Maximum ratings

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	Notes
$P_{burst1k}$	Pressure transducer, minimum burst pressure	≤ 1200 kPa rating	2000	—	—	kPa	D
f_{P0}	Pressure transducer, minimum natural resonance frequency	—	—	5	—	MHz	D
Q_P	Pressure transducer damping ratio	—	—	1	—	—	D
PA_N	Pressure transducer, sensitivity to vertical acceleration	–500 g ≤ A ≤ +500 g	—	0	—	Pa / g	C
PA_{neg}	Pressure transducer, sensitivity to vertical acceleration	A < –500 g	2	4.5	6.5	Pa / g	C
PA_{pos}	Pressure transducer, sensitivity to vertical acceleration	A > +500 g	–6.5	–4.5	–2	Pa / g	C
f_{A0}	Accelerometer, minimum natural resonance frequency	—	7	—	16	kHz	D
Q_A	Accelerometer, damping ratio	—	1	—	4	—	D
AP1k	Accelerometer, sensitivity to pressure	90 kPa ≤ P ≤ 1200 kPa	–1.5	—	+1.5	g / 1000 kPa	C
A_{stop2h}	Accelerometer, minimum acceleration to reach travel stop	≤ 100 g rating	–200	—	+200	g	D
A_{stop7h}	Accelerometer, minimum acceleration to reach travel stop	> 100 g rating	–700	—	+700	g	D
A_{CROSS}	Accelerometer, maximum cross axis sensitivity	X → Z, or Z → X, or X → Y, or Z → Y	–5	—	+5	%	D
m	Package Mass	—	—	0.2	—	gram	D
τ	Thermal time constant	—	—	101	—	sec	D

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7.2 Media compatibility

Media compatibility is based on media and test method described in NXP specification NXPOMS-999116894-4501.[2] Consult your sales representative for more details and specific requirements.

8 Mounting recommendations

The package should be mounted with the pressure port pointing away from the axis of tire rotation. By mounting the pressure port away from the axis of tire rotation, centrifugal force propels any contaminants out of the pressure port. In cases where the application must orient the pressure port pointing inward, care must be taken to assure contaminants do not reach inside the pressure port.

A plugged port exhibits no change in pressure and can be cross checked in the user software. Use the method described in user manual UM11227.[1]

Refer to application note AN1902[3] for proper printed circuit board attributes and recommendations.

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9 Package outline

Consult the most recently issued drawing before initiating or completing a design. The drawings are available for download at https://www.nxp.com/docs/en/package-information/SOT1931-1_D.pdf.

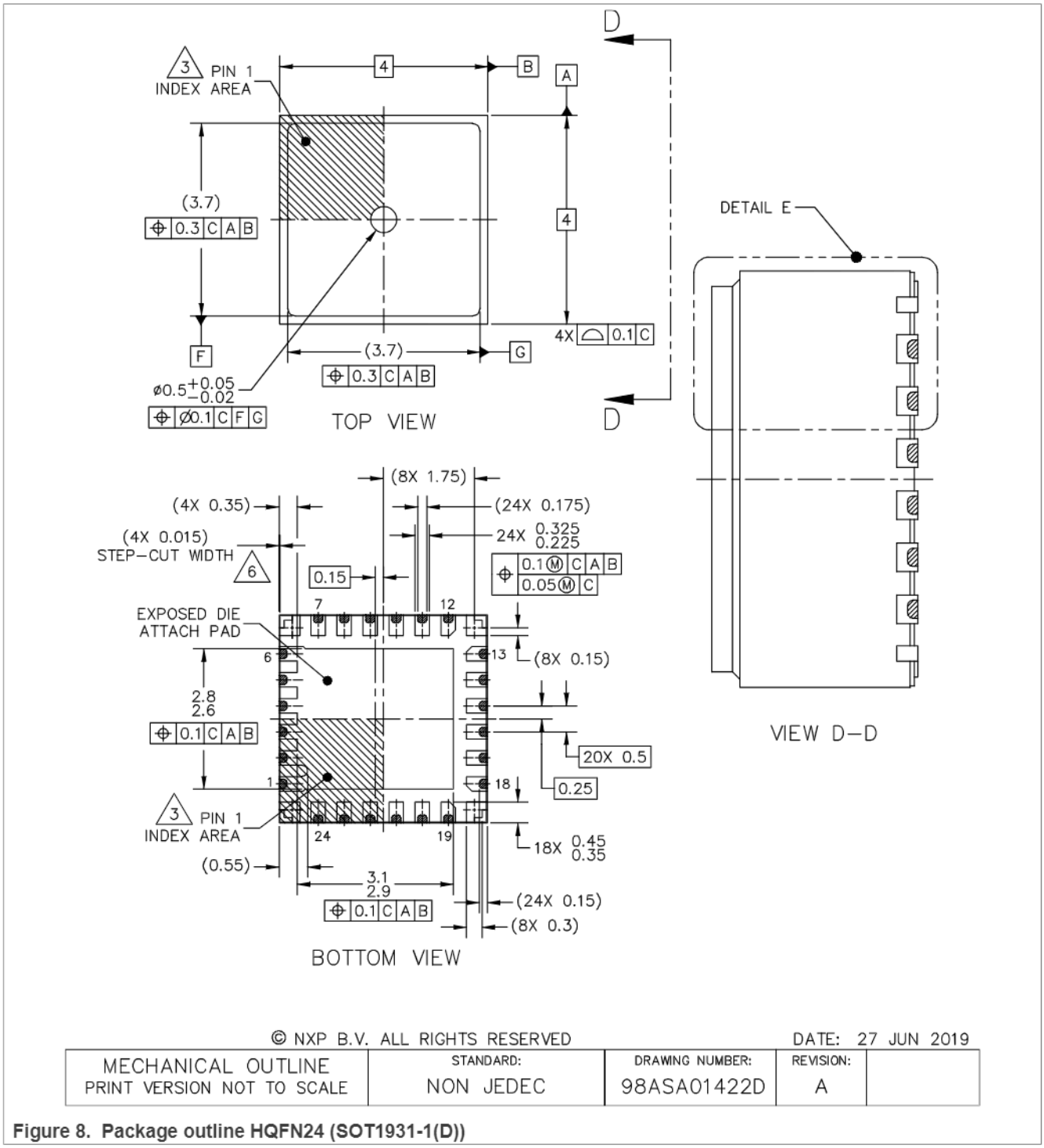
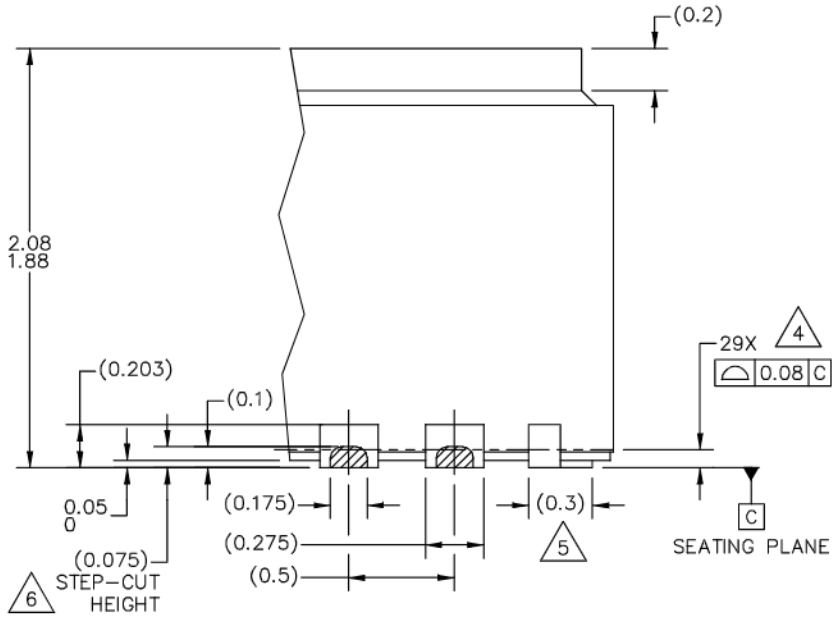


Figure 8. Package outline HQFN24 (SOT1931-1(D))

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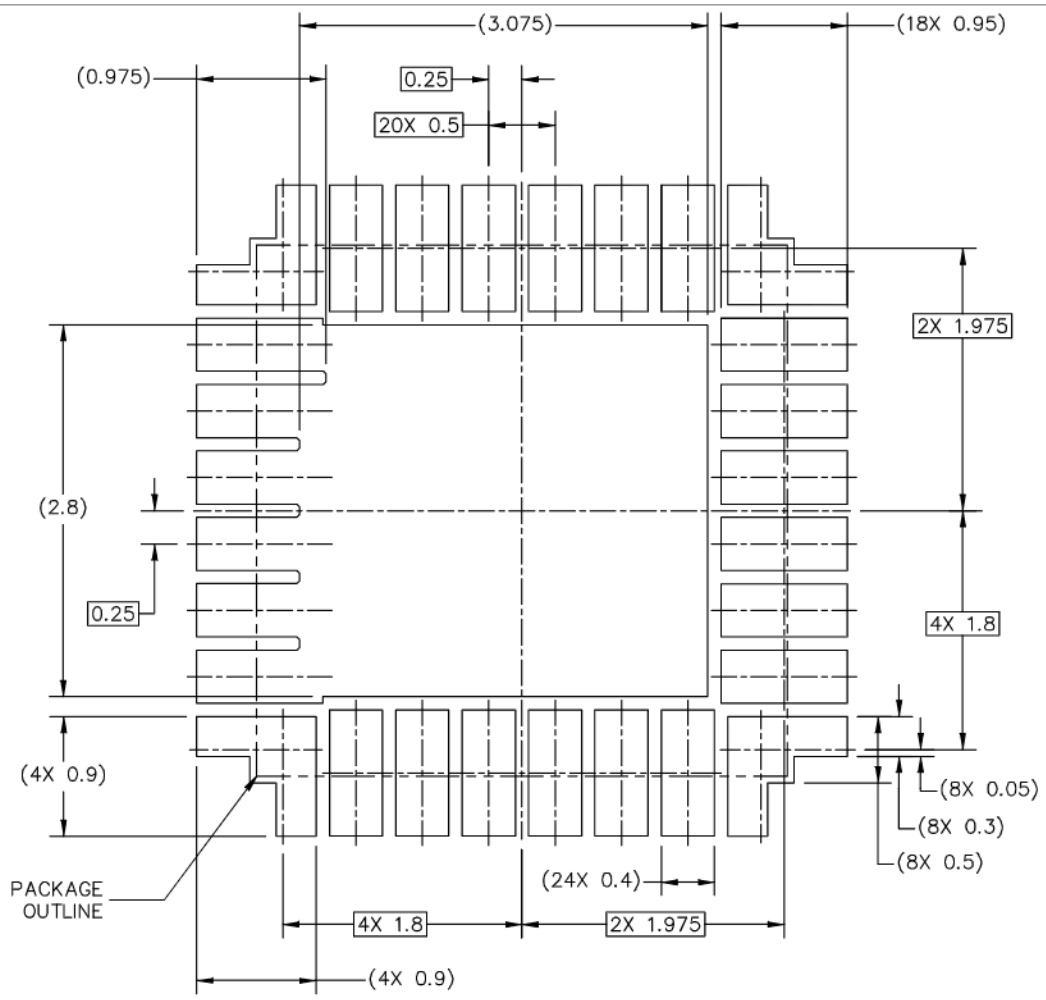
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MECHANICAL OUTLINE PRINT VERSION NOT TO SCALE	STANDARD: NON JEDEC	DRAWING NUMBER: 98ASA01422D	REVISION: A	

Figure 9. Package outline detail HQFN24 (SOT1931-1(D))

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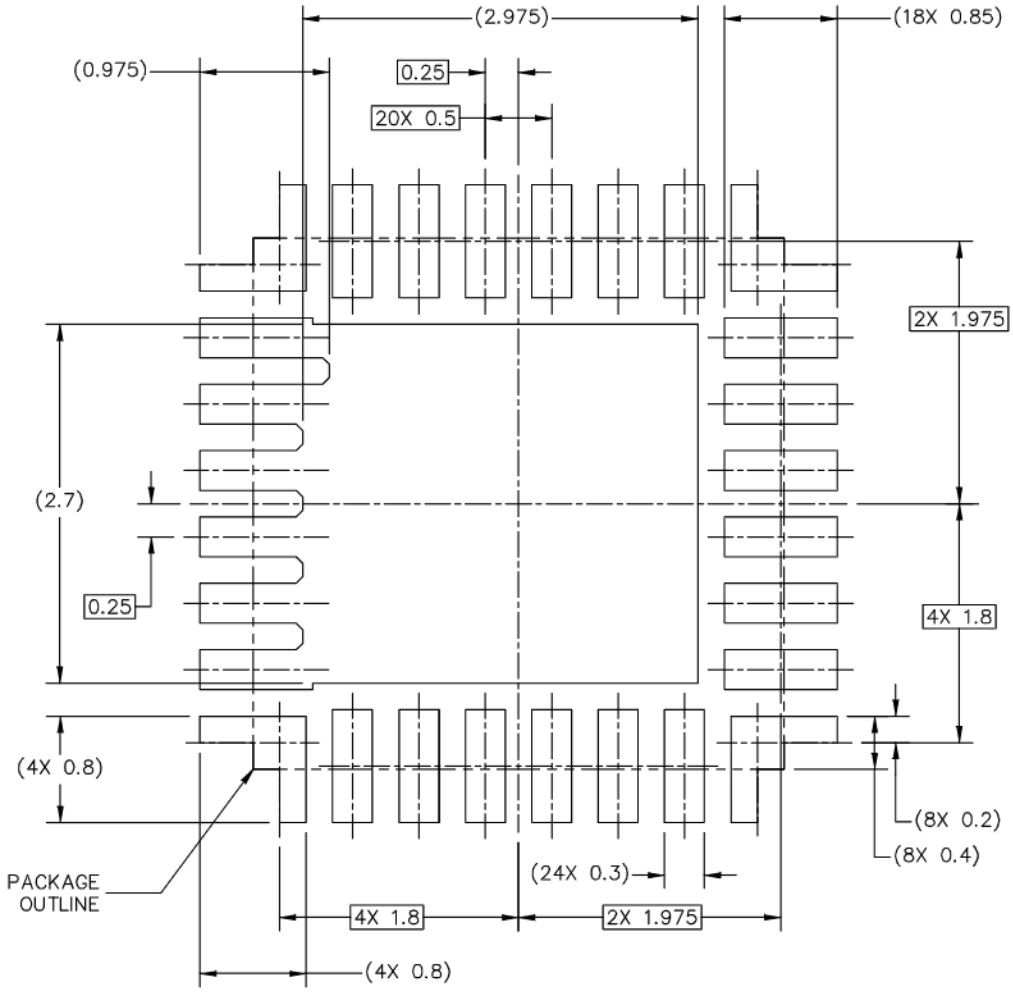
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Figure 10. Reflow soldering footprint part1 for HQFN24 (SOT1931-1(D))

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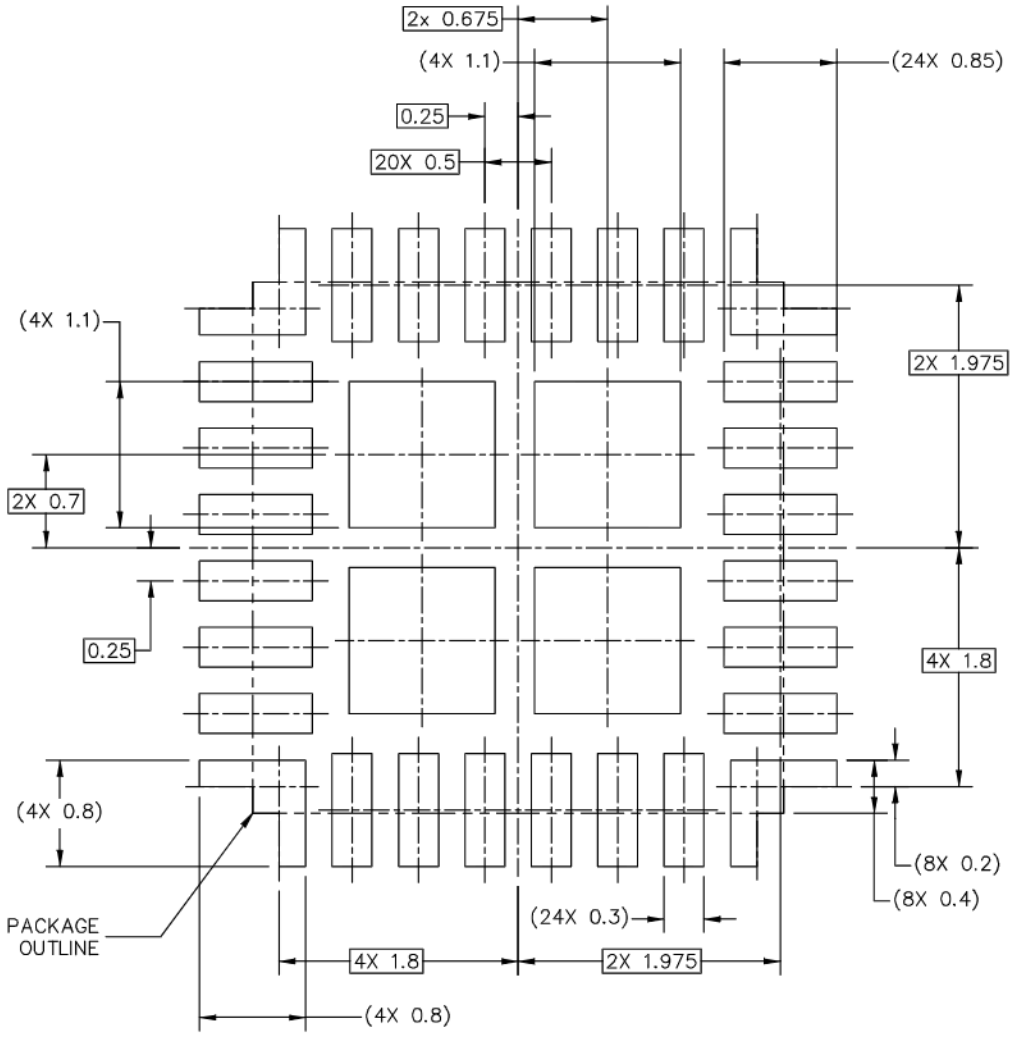
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Figure 11. Reflow soldering footprint part2 for HQFN24 (SOT1931-1(D))

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RECOMMENDED STENCIL THICKNESS 0.125

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Figure 12. Reflow soldering footprint part3 for HQFN24 (SOT1931-1(D))

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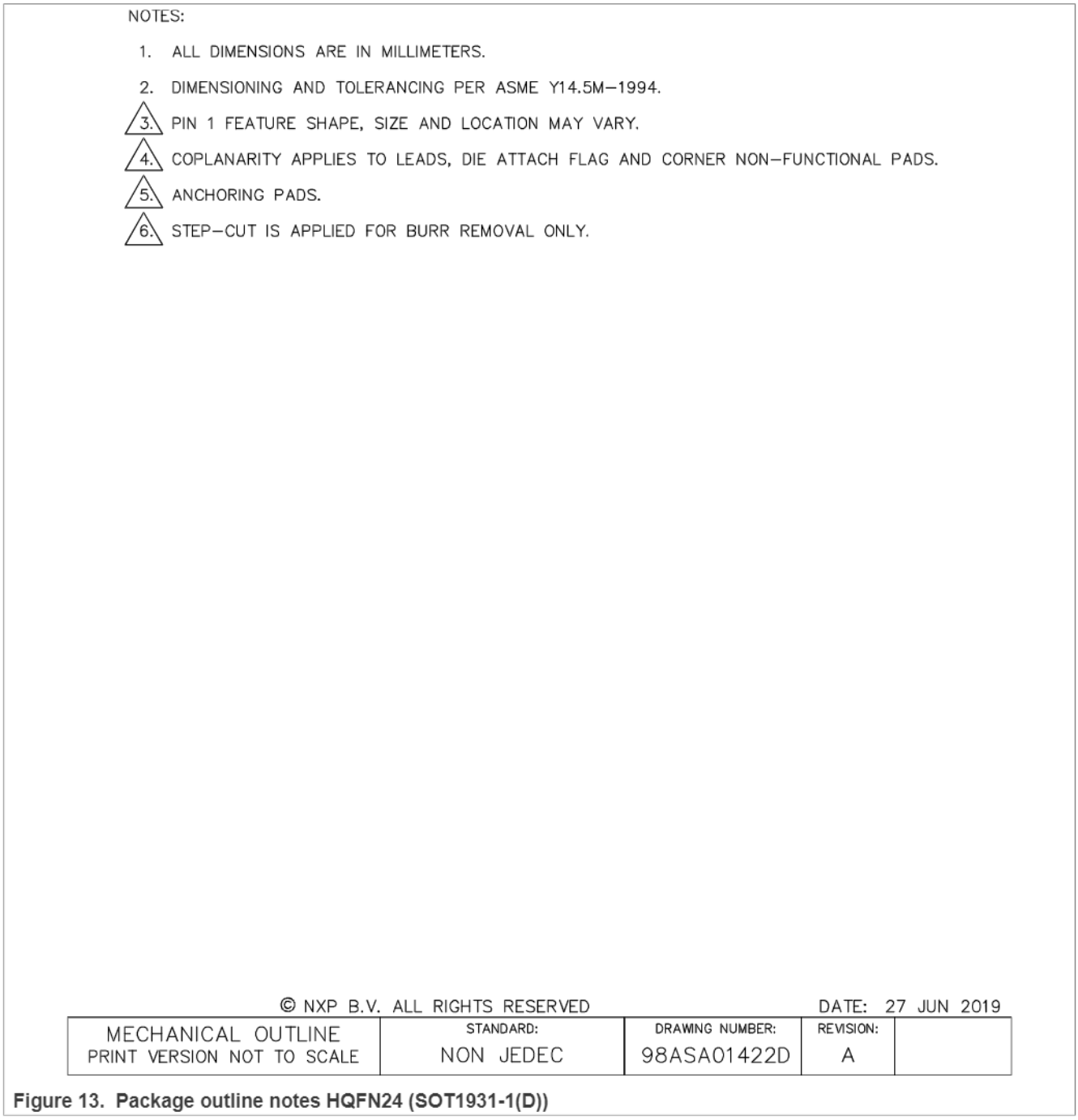


Figure 13. Package outline notes HQFN24 (SOT1931-1(D))

10 References

NXP reference documents

[1] UM11227, *NTM88 family of tire pressure monitor sensors*

[2] NXP Specification NXPOMS-999116894-4501, *Media test for TPMS MCM automotive pressure sensors*

[3] AN1902, *Assembly guidelines for QFN (quad flat no-lead) and SON (small outline no-lead) packages*

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11 Revision history

Table 30. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NTM88Hxx5S v.1.1	20230623	Objective data sheet	—	NTM88Hxx5S v.1
Modifications:	• Table 2, revised the values for Code H.			
NTM88Hxx5S v.1	20221012	Objective data sheet	—	NTM88xxx5S v.1.2

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12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
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Tables

Tab. 1. Ordering information 2
Tab. 2. Ordering options 2
Tab. 3. Content of the hardware version byte at SPI address $1542 3
Tab. 4. Content of the hardware version byte at SPI address $1543 3
Tab. 5. 16-bit SPI command to read the NTM88 hardware version at SPI address $1542 4
Tab. 6. 16-bit SPI command to read the NTM88 hardware version at SPI address $1543 4
Tab. 7. Example of SPI response from the NTM88 to the command 0x550A 4
Tab. 8. Example of SPI response from the NTM88 to the command 0x550F 4
Tab. 9. Pin description 6
Tab. 10. Electrical and mechanical specification note definition table 9
Tab. 11. Maximum ratings 10
Tab. 12. Operating range 10
Tab. 13. Charge consumptions 12
Tab. 14. Clocks and thresholds 12
Tab. 15. Power-on reset 13
Tab. 16. GPIO port pins 13
Tab. 17. SPI timing 14
Tab. 18. Temperature measurement 14
Tab. 19. Voltage measurement characteristics 15
Tab. 20. External pin voltage measurement 16
Tab. 21. Pressure measurement characteristics (90 kPa to 930 kPa) range 16
Tab. 22. Acceleration measurement characteristic (– 80 g to +90 g) range option 17
Tab. 23. Acceleration measurement characteristic (– 360 g to +400 g) range option 18
Tab. 24. Acceleration measurement characteristic (– 120 g to +520 g) range option 19
Tab. 25. Acceleration measurement characteristic (– 175 g to +550 g) range option 20
Tab. 26. Acceleration measurement characteristic (– 400 g to +400 g) range option 22
Tab. 27. LFR characteristics 24
Tab. 28. Radio frequency transmitter characteristics 24
Tab. 29. Maximum ratings 28
Tab. 30. Revision history 36

Figures

Fig. 1. Block diagram 5
Fig. 2. Pin configuration 6
Fig. 3. NTM88Hxx5S orientation at rest. 9
Fig. 4. Dynamic power adjustment — 315 MHz 27
Fig. 5. Dynamic power adjustment — 434 MHz 27
Fig. 6. RF output power measurement configuration 27
Fig. 7. Battery performance test configuration 28
Fig. 8. Package outline HQFN24 (SOT1931-1(D)) 30
Fig. 9. Package outline detail HQFN24 (SOT1931-1(D)) 31
Fig. 10. Reflow soldering footprint part1 for HQFN24 (SOT1931-1(D)) 32
Fig. 11. Reflow soldering footprint part2 for HQFN24 (SOT1931-1(D)) 33
Fig. 12. Reflow soldering footprint part3 for HQFN24 (SOT1931-1(D)) 34
Fig. 13. Package outline notes HQFN24 (SOT1931-1(D)) 35

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Contents

1 General description 1
2 Features and benefits 1
3 Ordering information 2
3.1 Hardware version numbers 3
4 Block diagram 4
5 Pinning information 6
5.1 Pinning 6
5.2 Pin description 6
5.3 Orientation 9
6 Electrical specifications 9
6.1 Maximum ratings (electrical) 9
6.2 Operating conditions 10
6.3 Charge consumptions 12
6.4 Clocks and thresholds 12
6.5 Power-on reset operation 13
6.6 GPIO port pins 13
6.7 SPI timing characteristics 14
6.8 Temperature measurement characteristics 14
6.9 Voltage measurement characteristics 15
6.10 Pressure measurement characteristics 16
6.10.1 Pressure measurement characteristic (90 kPa to 930 kPa) range 16
6.11 Acceleration measurement characteristics 17
6.11.1 Acceleration measurement characteristics (–80 g to +90 g) range option 17
6.11.2 Acceleration measurement characteristic (–360 g to +400 g) range option 18
6.11.3 Acceleration measurement characteristic (–120 g to +520 g) range option 19
6.11.4 Acceleration measurement characteristic (–175 g to +550 g) range option 20
6.11.5 Acceleration measurement characteristic (–400 g to +400 g) range option 22
6.12 Low frequency receiver characteristics 24
6.13 Radio frequency transmitter characteristics 24
6.14 Power consumption RF transmissions 26
7 Mechanical specifications 28
7.1 Maximum ratings (mechanical) 28
7.2 Media compatibility 29
8 Mounting recommendations 29
9 Package outline 30
10 References 35
11 Revision history 36
12 Legal information 37

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